



US00D505923S

(12) **United States Design Patent** (10) **Patent No.:** **US D505,923 S**  
**Okuyama et al.** (45) **Date of Patent:** **\*\* Jun. 7, 2005**

(54) **SEMICONDUCTOR ELEMENT**

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(JP)

(73) Assignee: **Sony Corporation**, Tokyo (JP)

(\*\*) Term: **14 Years**

(21) Appl. No.: **29/193,674**

(22) Filed: **Nov. 13, 2003**

(51) **LOC (8) Cl.** ..... **13-03**

(52) **U.S. Cl.** ..... **D13/182**

(58) **Field of Search** ..... D13/182; D3/5;  
D21/834; 216/2, 11; 257/77, 94, 95, 190;  
313/309, 311; 369/126; 438/20, 116; 445/50

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*Primary Examiner*—Stella Reid

*Assistant Examiner*—Selina Sikder

(74) *Attorney, Agent, or Firm*—Rader, Fishman & Grauer  
PLLC

(57) **CLAIM**

The ornamental design for a semiconductor element, as  
shown and described.

**DESCRIPTION**

FIG. 1 is a perspective view of a first embodiment of a  
semiconductor element showing our new design;  
FIG. 2 is a front elevational view thereof;  
FIG. 3 is a rear elevational view thereof;  
FIG. 4 is a left side elevational view thereof;  
FIG. 5 is a right side elevational view thereof; and  
FIG. 6 is a top plan view thereof.

FIG. 7 is a perspective view of a second embodiment of a  
semiconductor element showing our new design;  
FIG. 8 is a front elevational view thereof;  
FIG. 9 is a rear elevational view thereof;  
FIG. 10 is a left side elevational view thereof;  
FIG. 11 is a right side elevational view thereof; and  
FIG. 12 is a top plan view thereof.

FIG. 13 is a perspective view of a third embodiment of a  
semiconductor element showing our new design;  
FIG. 14 is a front elevational view thereof;  
FIG. 15 is a rear elevational view thereof;  
FIG. 16 is a left side elevational view thereof;  
FIG. 17 is a right side elevational view thereof; and  
FIG. 18 is a top plan view thereof.

FIG. 19 is a perspective view of a fourth embodiment of a  
semiconductor element showing our new design;  
FIG. 20 is a front elevational view thereof;  
FIG. 21 is a rear elevational view thereof;  
FIG. 22 is a left side elevational view thereof;  
FIG. 23 is a right side elevational view thereof; and  
FIG. 24 is a top plan view thereof.

The projecting part on the top and lower part of the semi-  
conductor element are opaque or transparent.

FIG. 25 is a perspective view of a fifth embodiment of a  
semiconductor element showing our new design;  
FIG. 26 is a front elevational view thereof;  
FIG. 27 is a rear elevational view thereof;  
FIG. 28 is a left side elevational view thereof;  
FIG. 29 is a right side elevational view thereof; and  
FIG. 30 is a top plan view thereof.

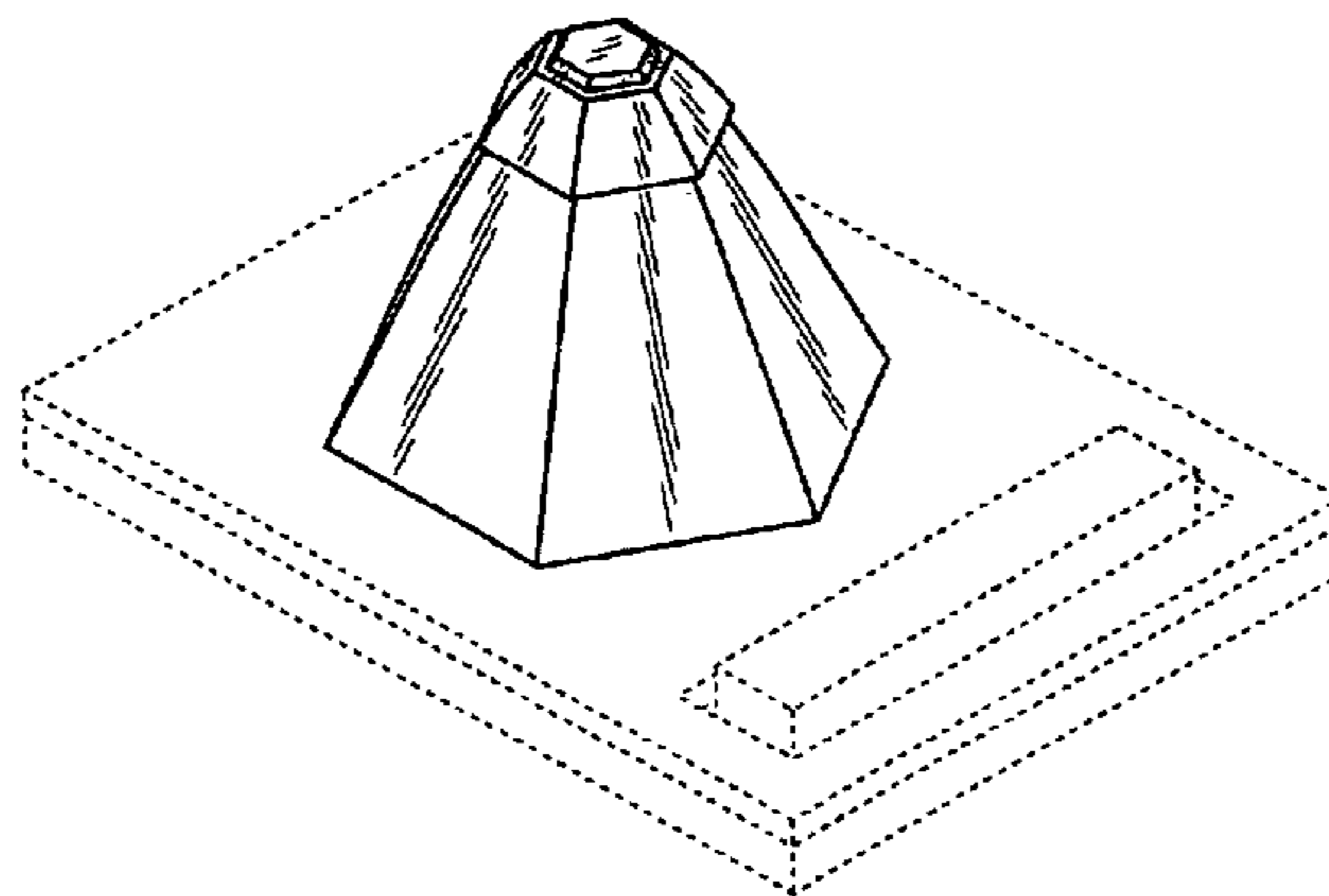
The projecting part on the top and lower part of the semi-  
conductor element are opaque or transparent.

FIG. 31 is a perspective view of a sixth embodiment of a  
semiconductor element showing our new design;  
FIG. 32 is a front elevational view thereof;  
FIG. 33 is a rear elevational view thereof;  
FIG. 34 is a left side elevational view thereof;  
FIG. 35 is a right side elevational view thereof; and,  
FIG. 36 is a top plan view thereof.

The projecting part on the top and lower part of the semi-  
conductor element are opaque or transparent.

The broken lines shown in the Figures are for illustrative  
purposes only and form no part of the claimed design. A  
bottom plan view in the first, second, third, fourth, fifth, and  
sixth embodiments is not part of the claimed design.

**1 Claim, 24 Drawing Sheets**



# US D505,923 S

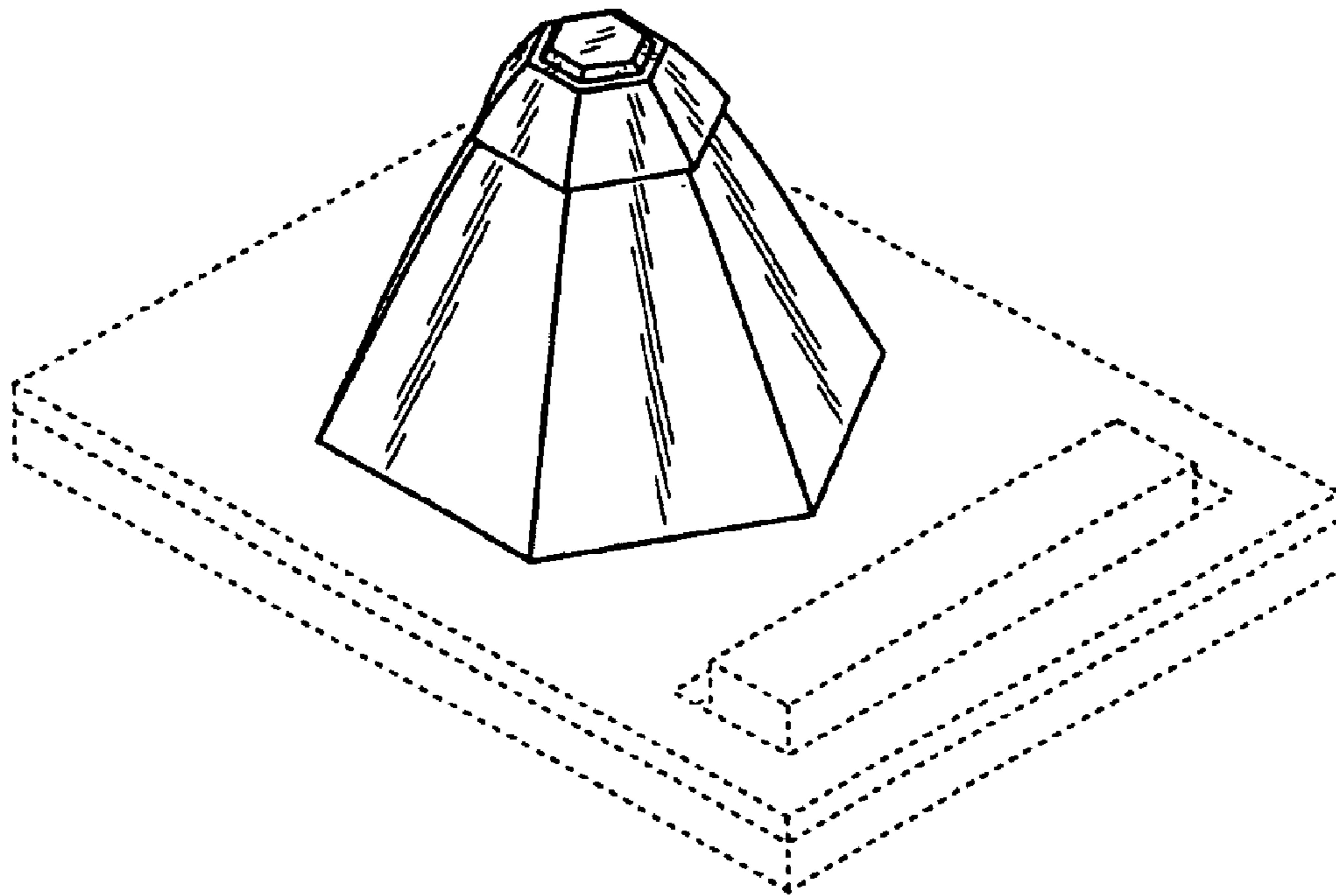
Page 2

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*FIG. 1*

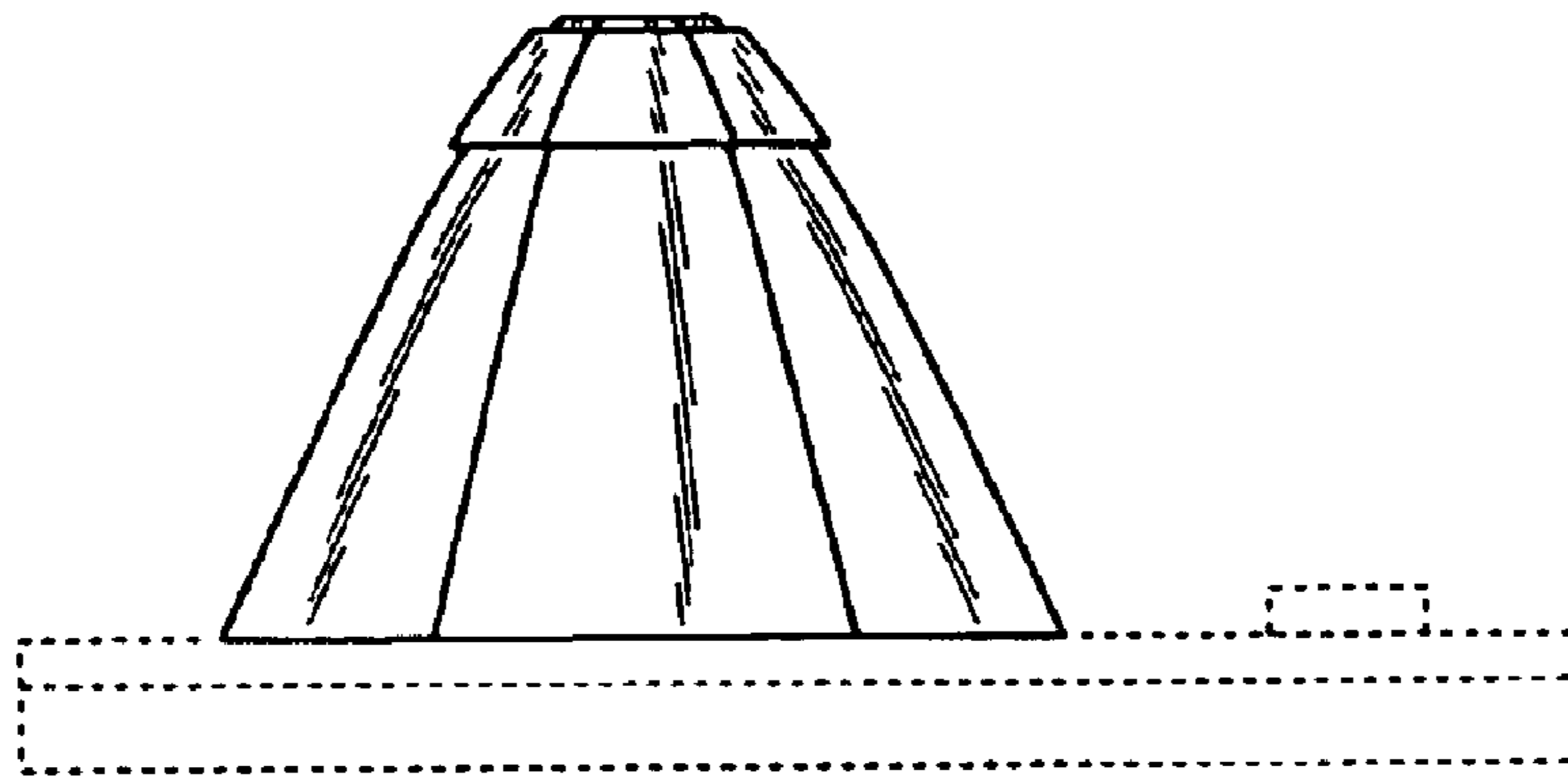


FIG. 2

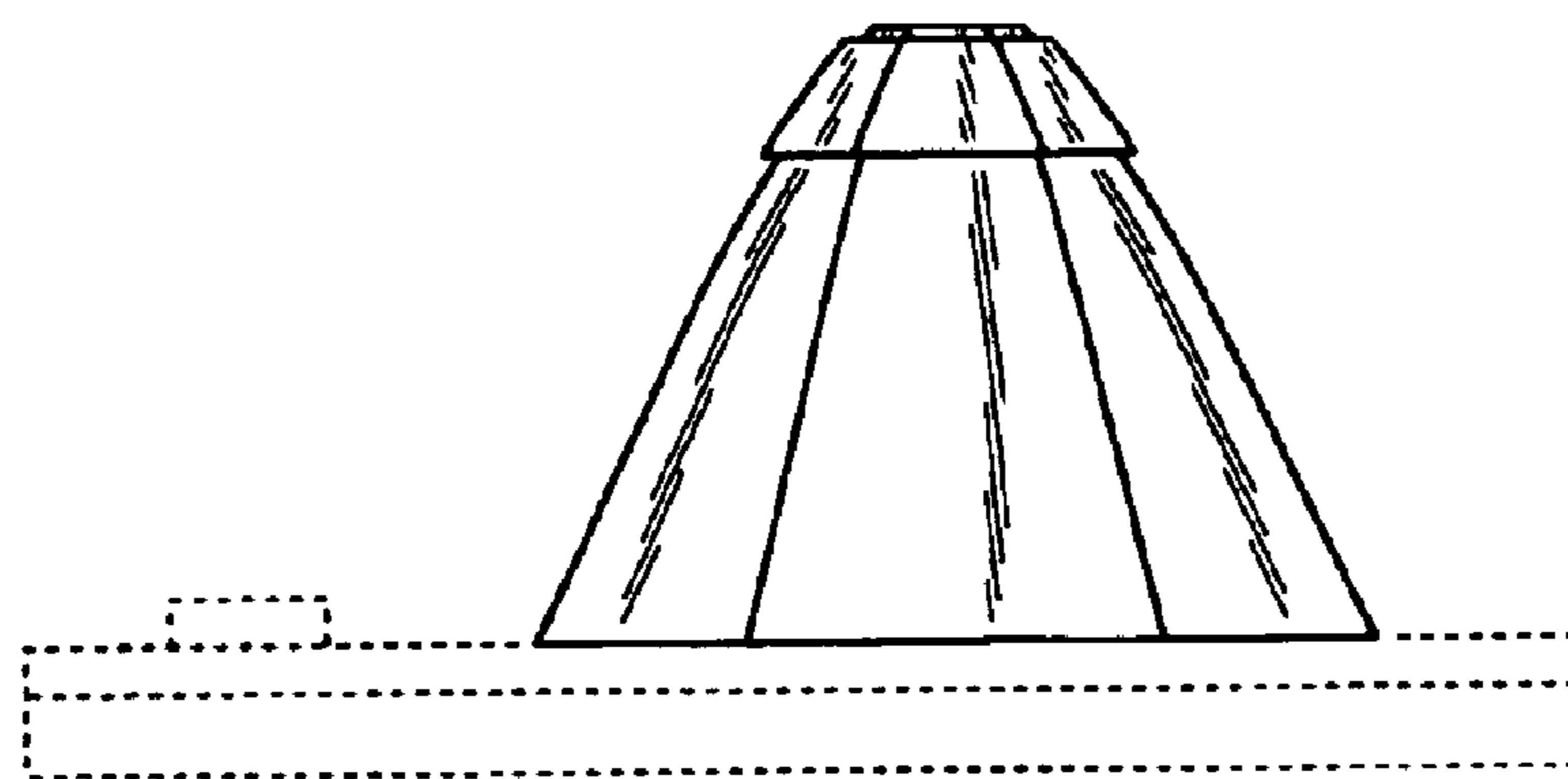


FIG. 3

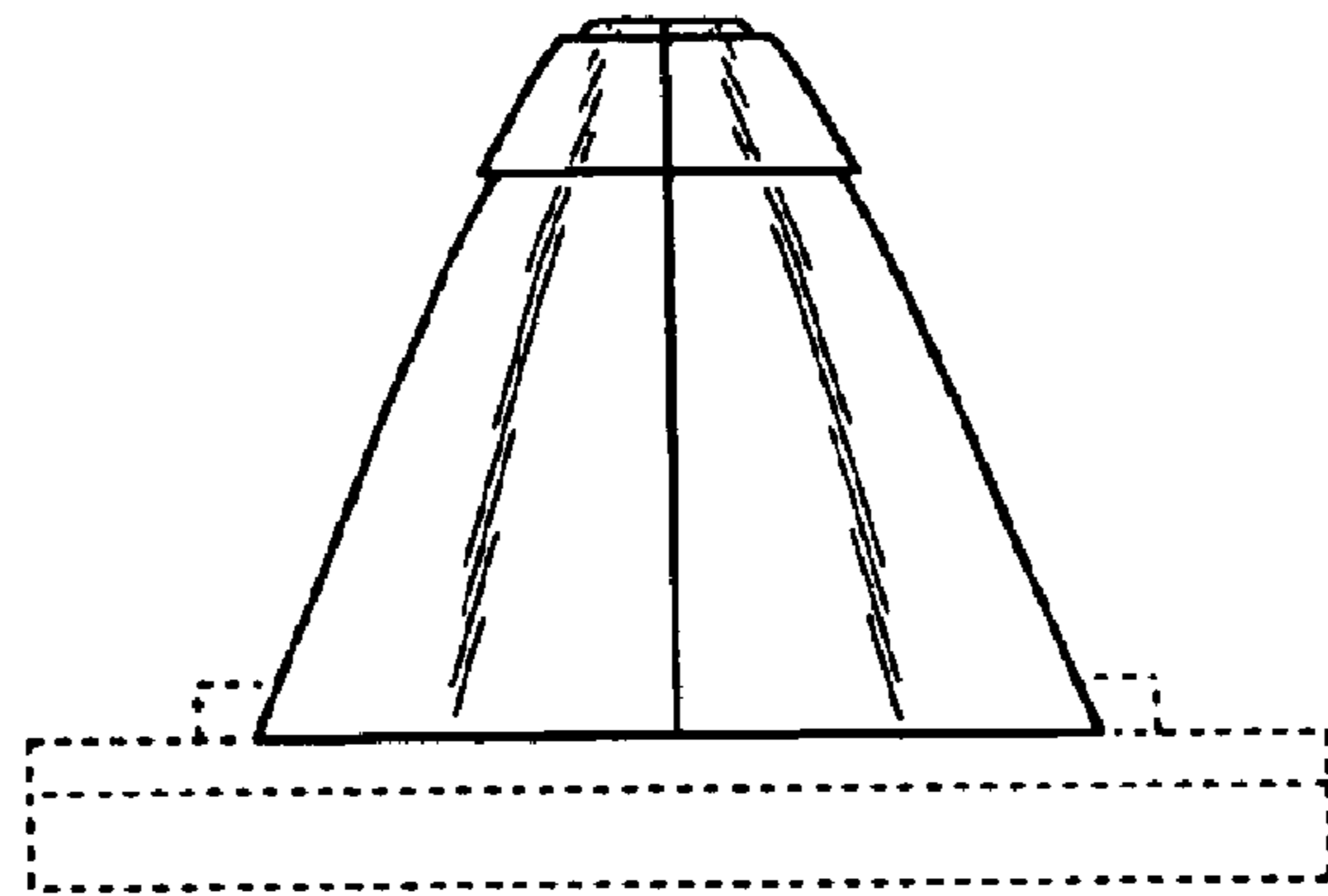


FIG. 4

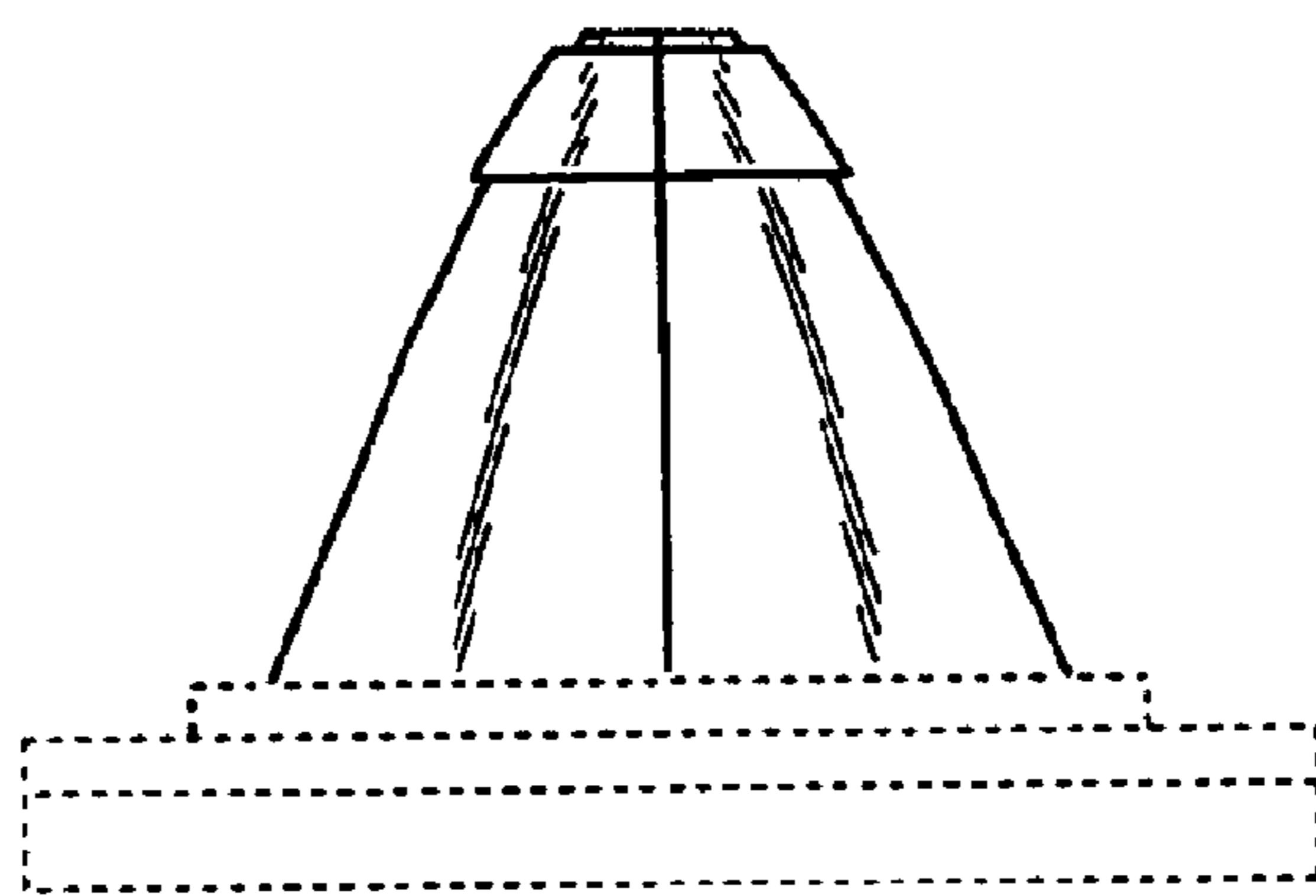


FIG. 5

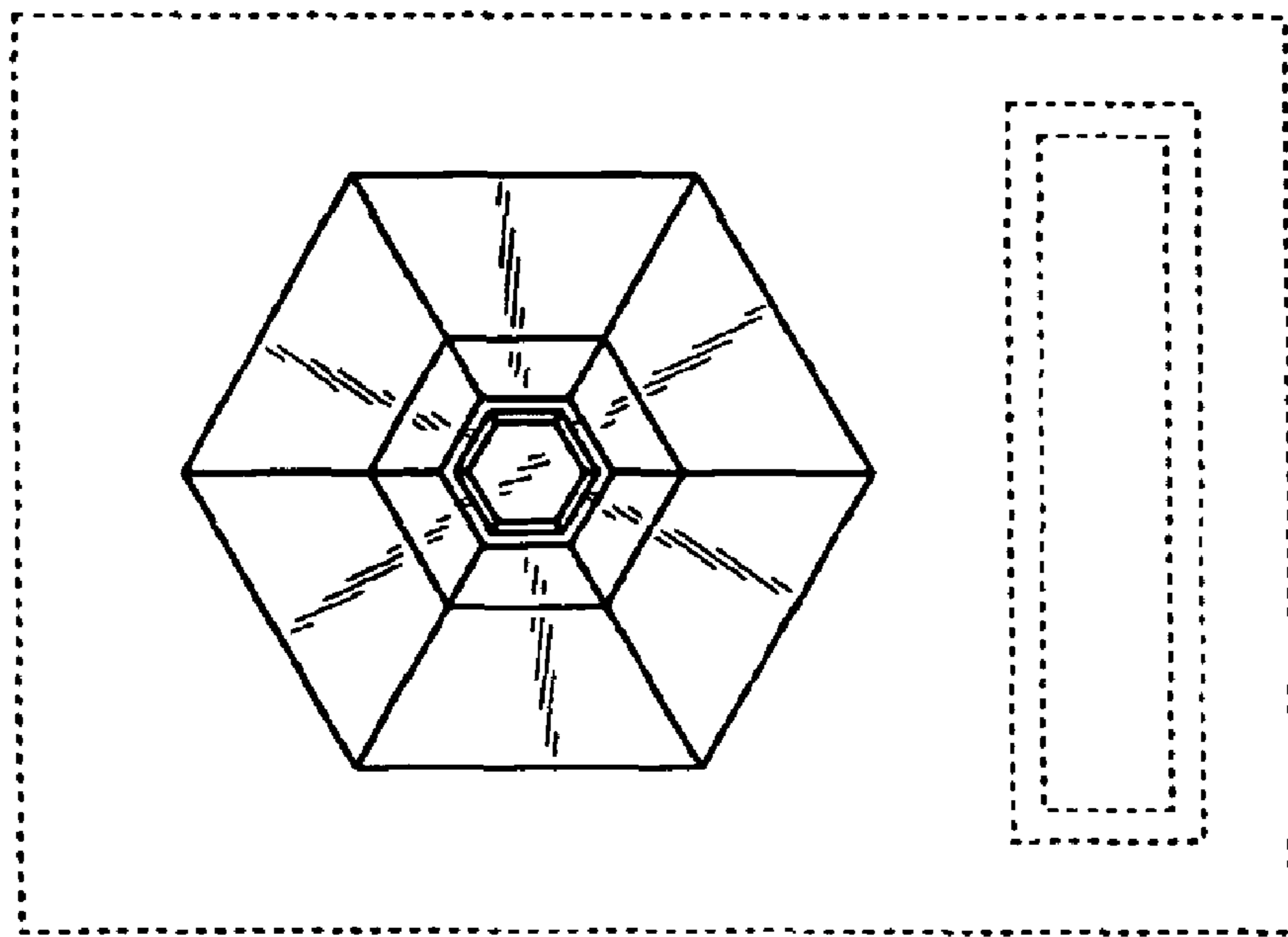
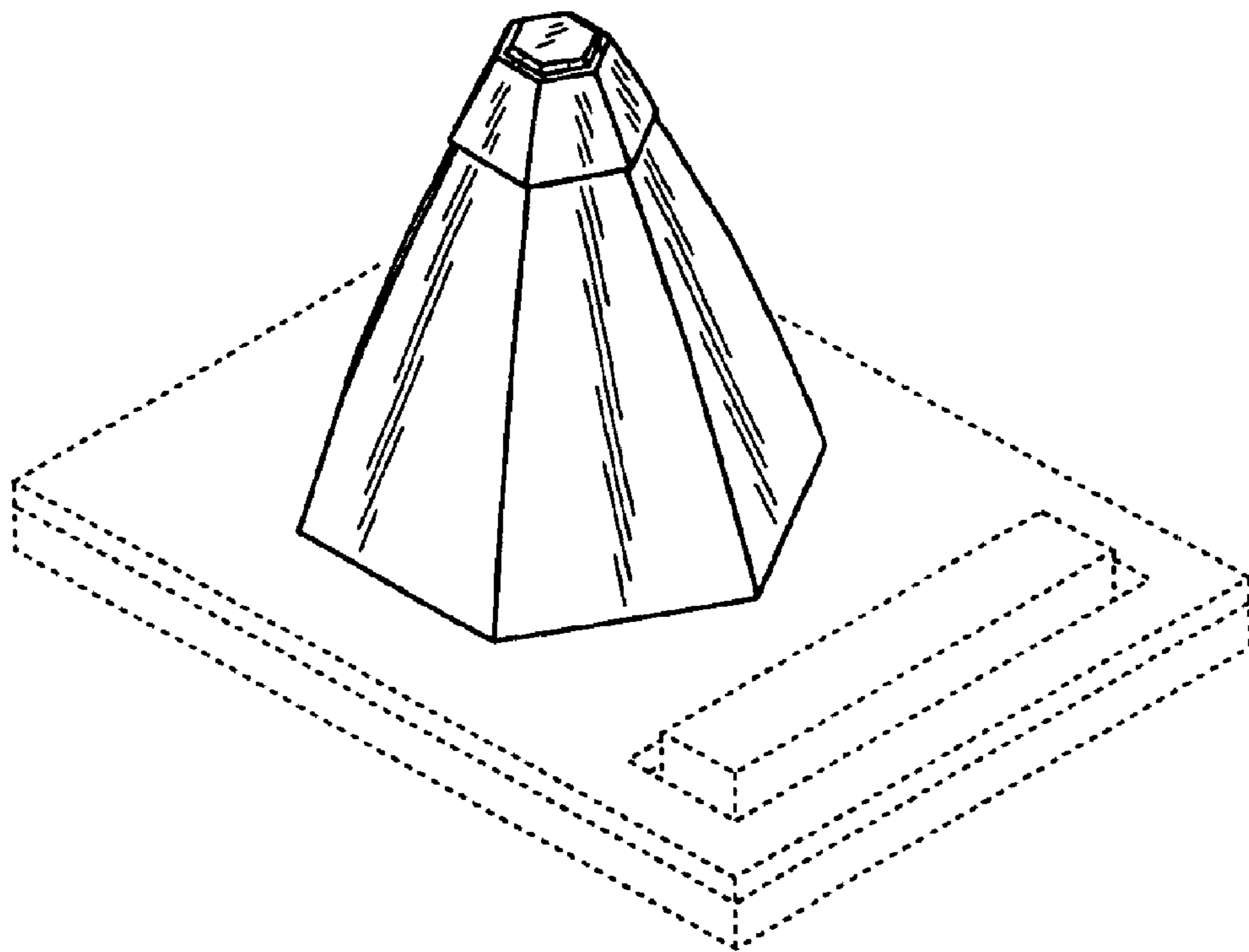


FIG. 6



**FIG. 7**

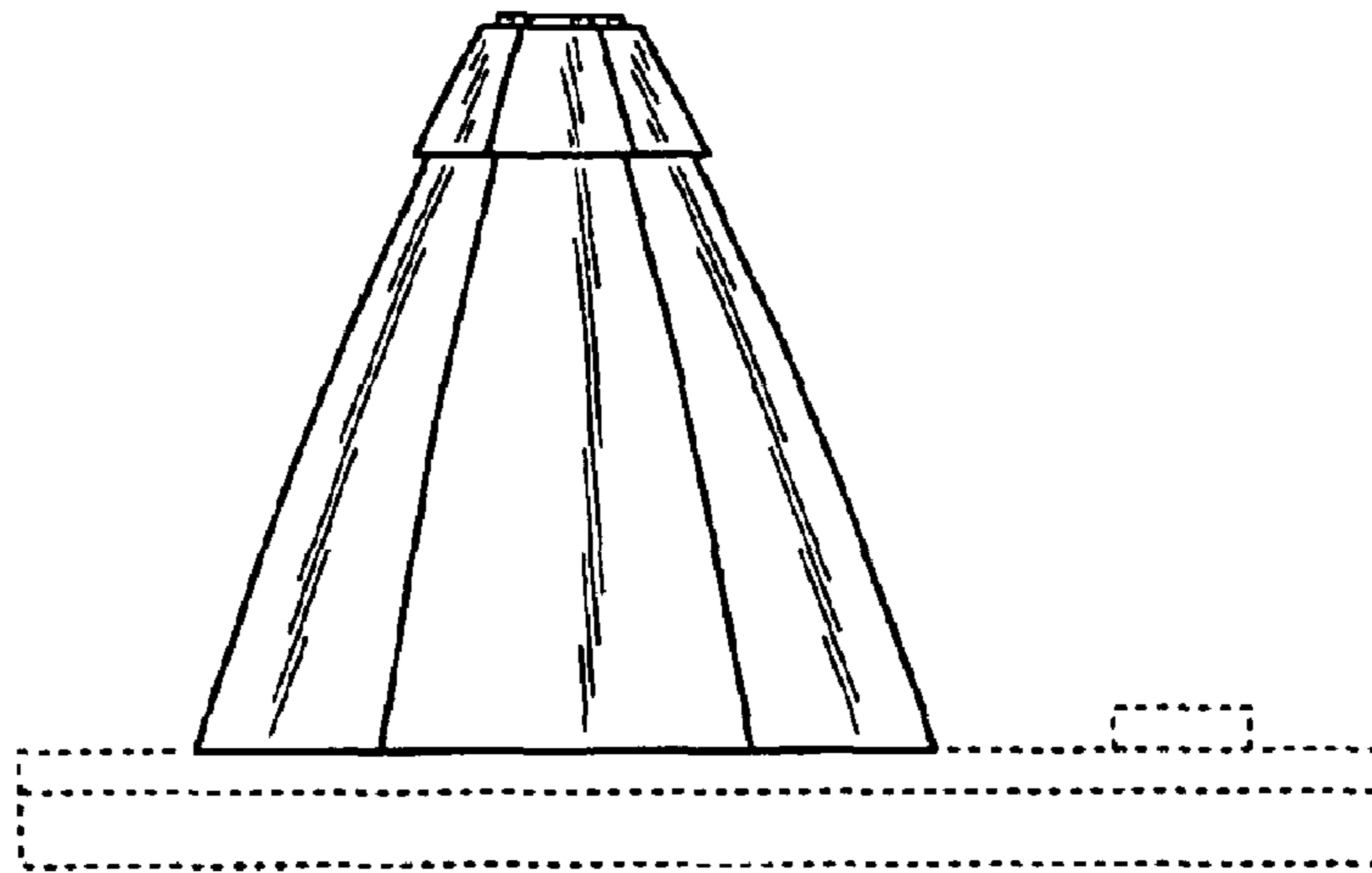


FIG. 8

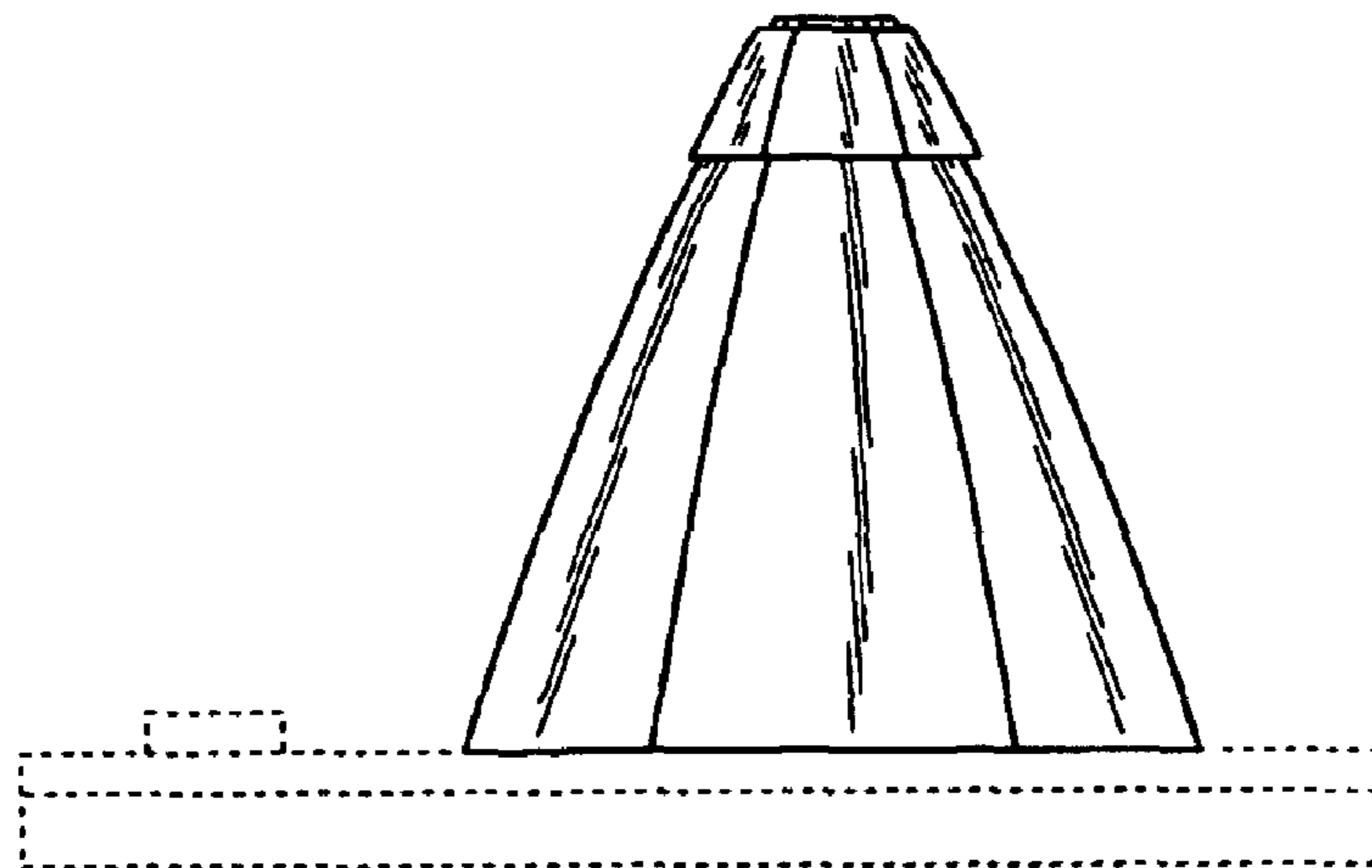


FIG. 9



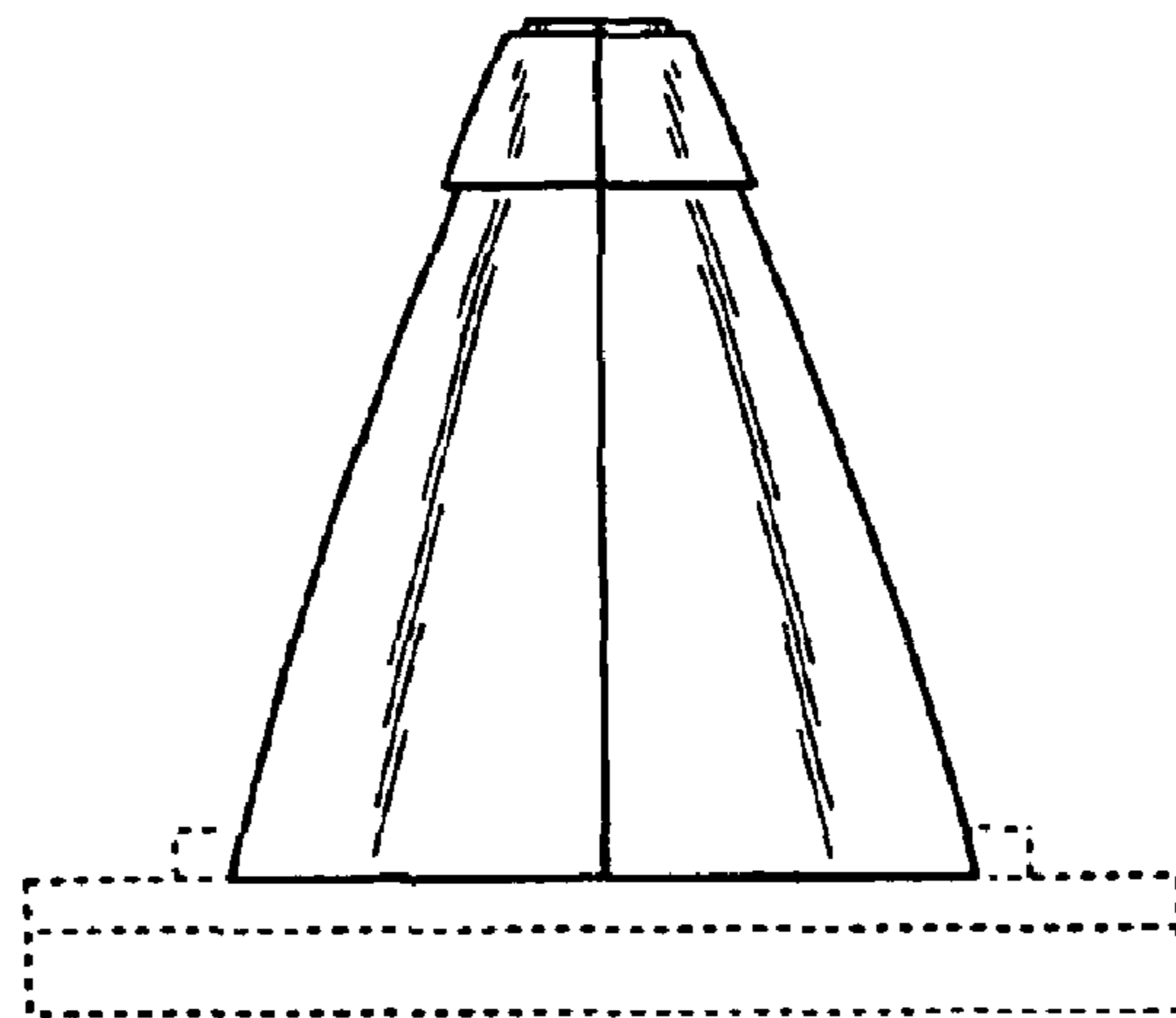


FIG. 10

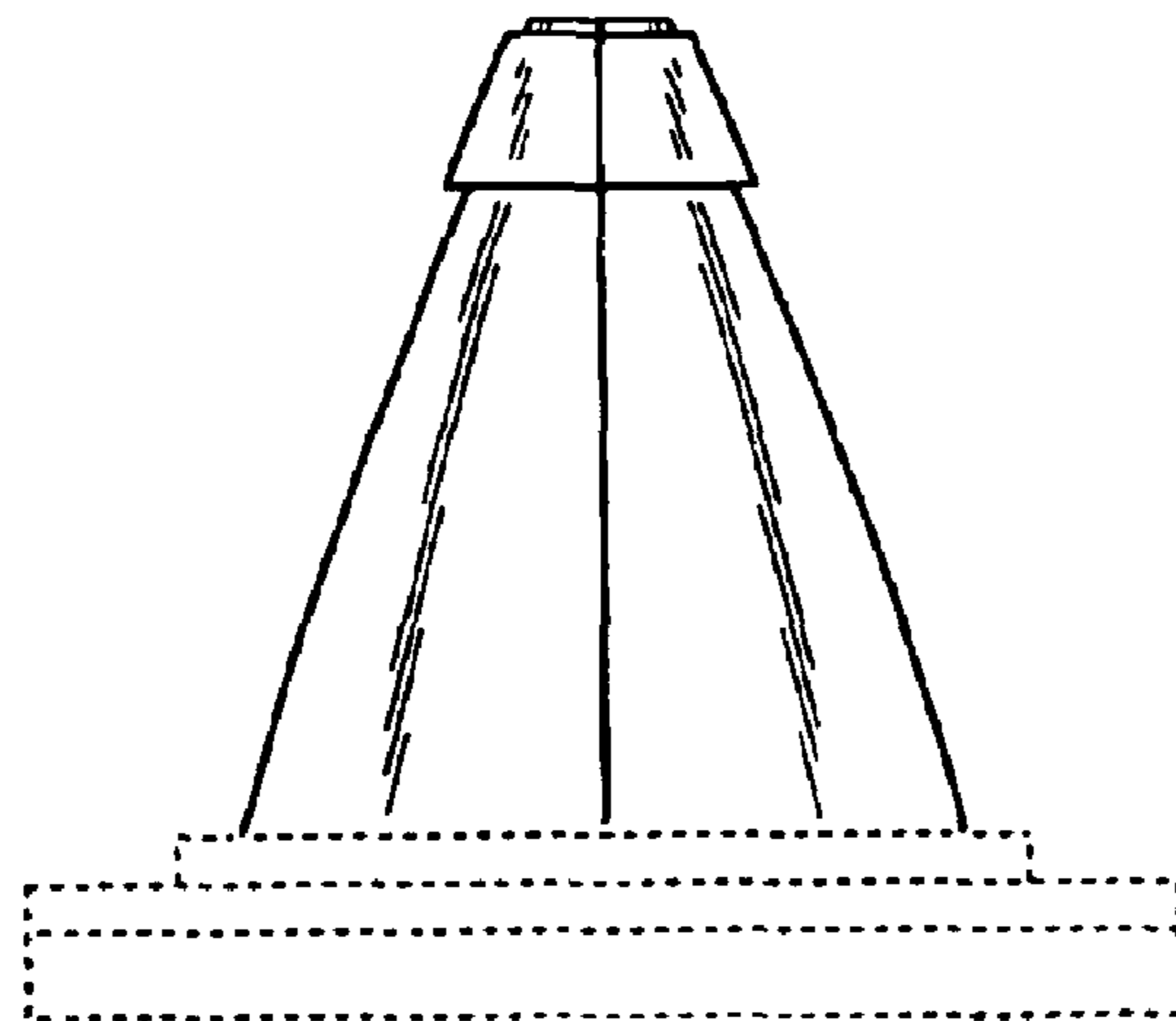


FIG. 11

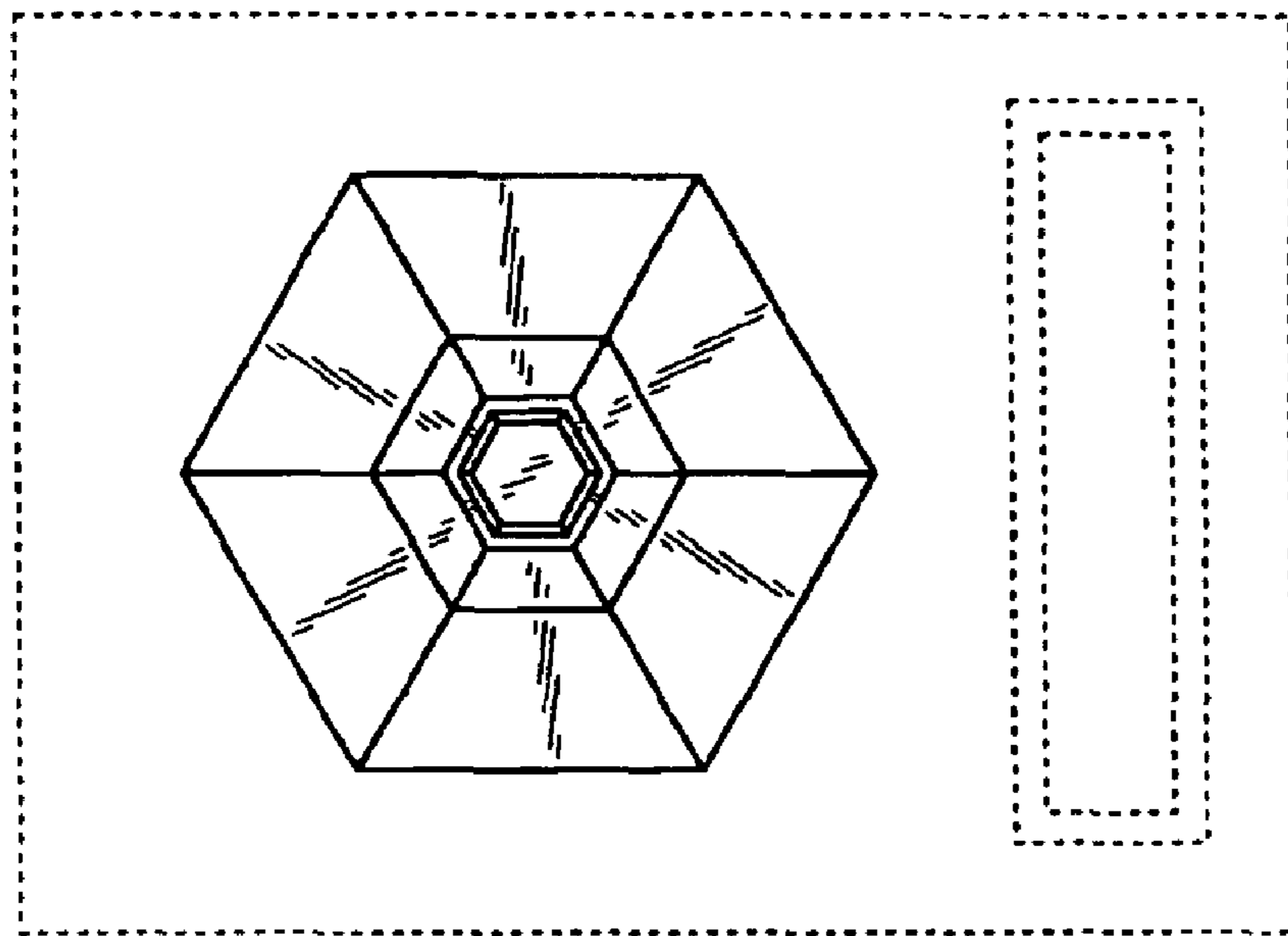


FIG. 12

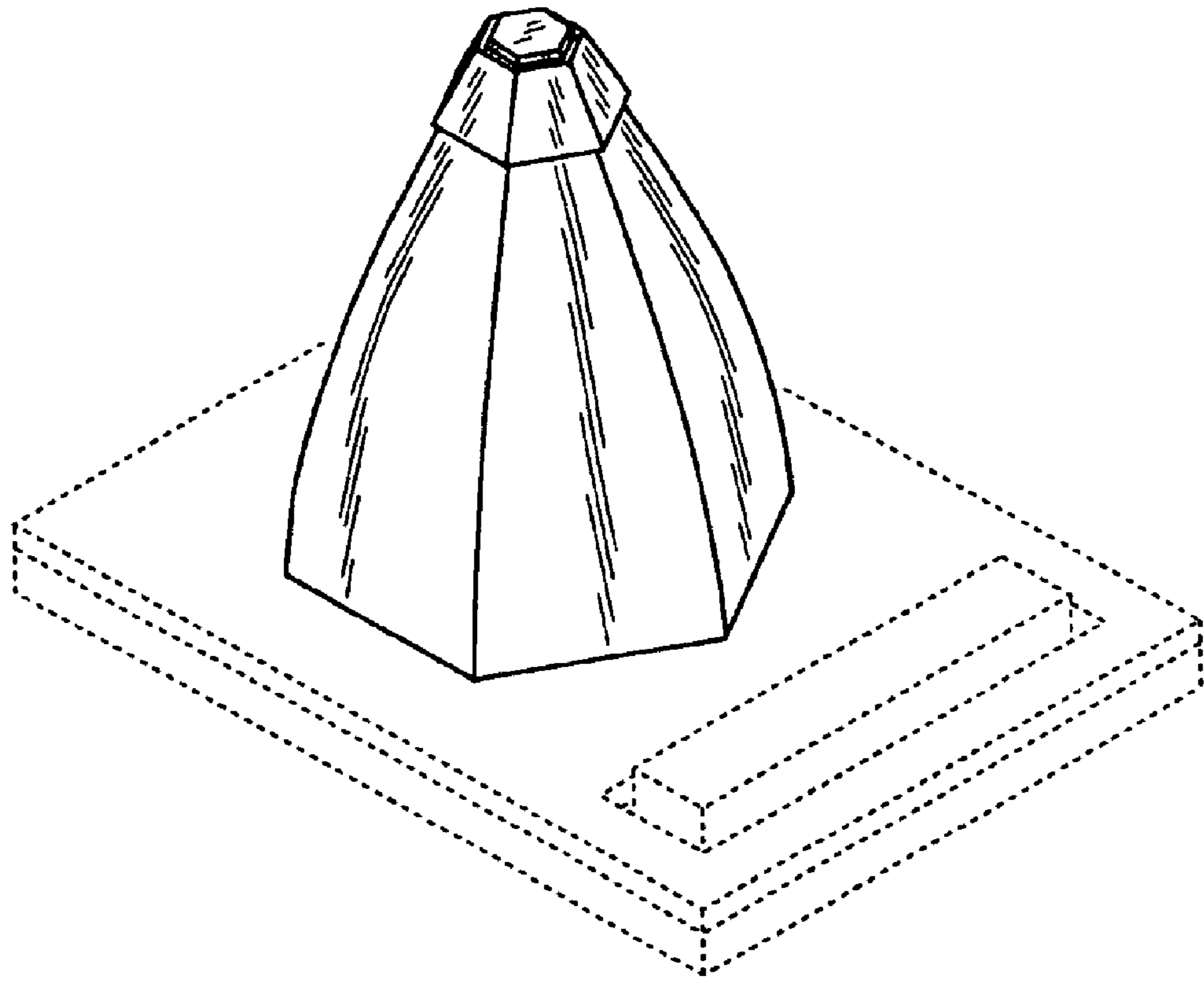


FIG. 13

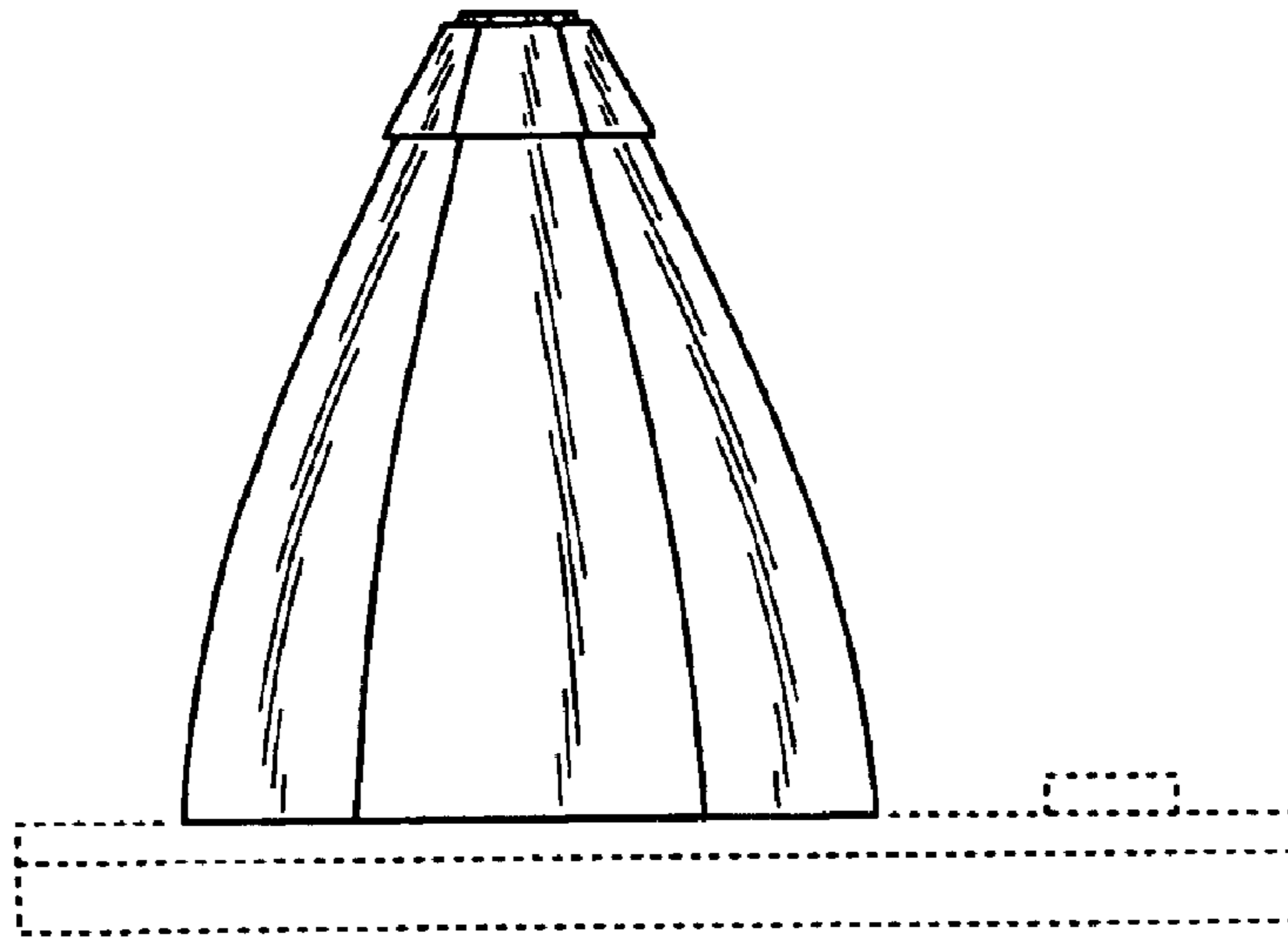


FIG. 14

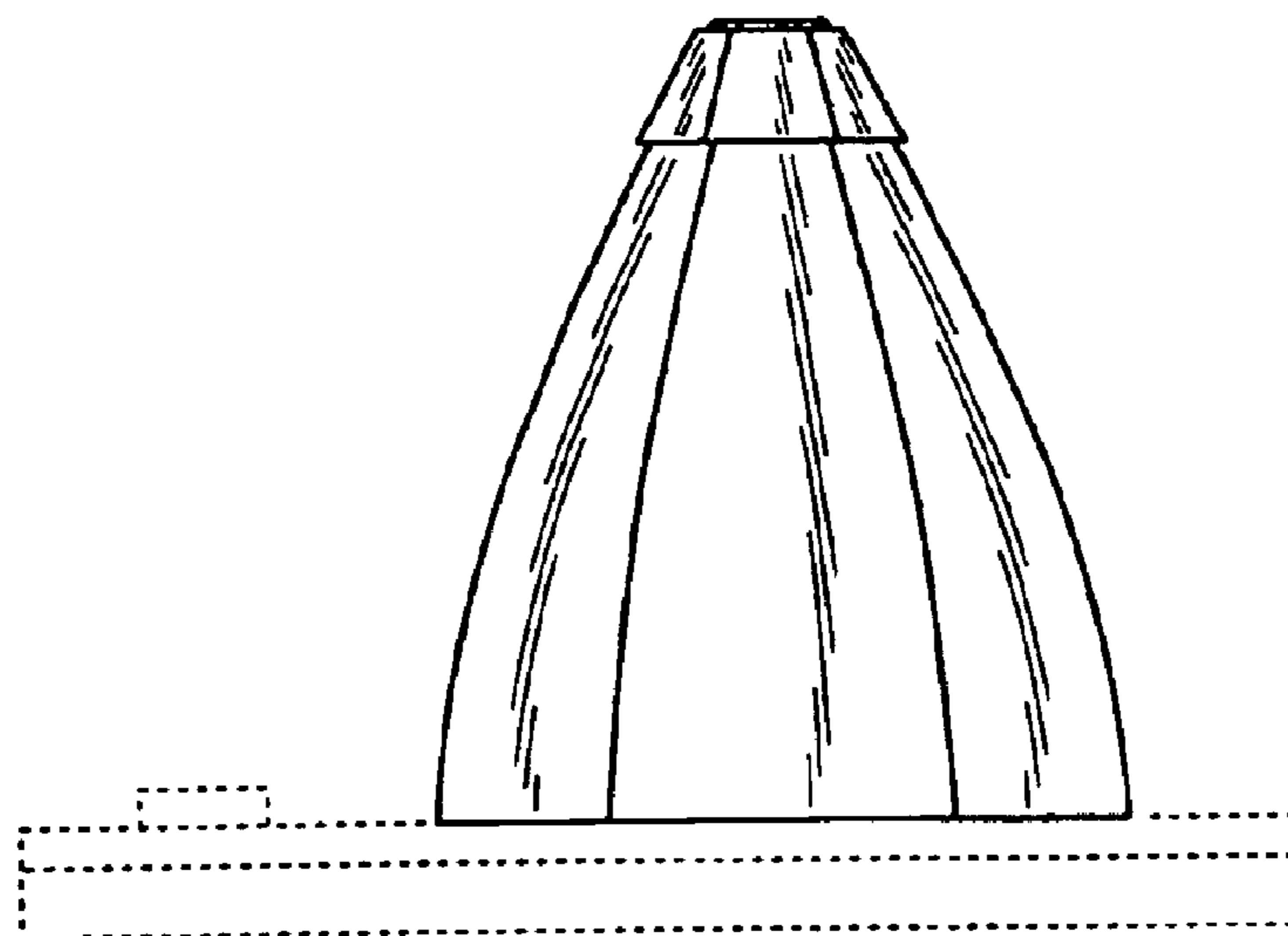


FIG. 15

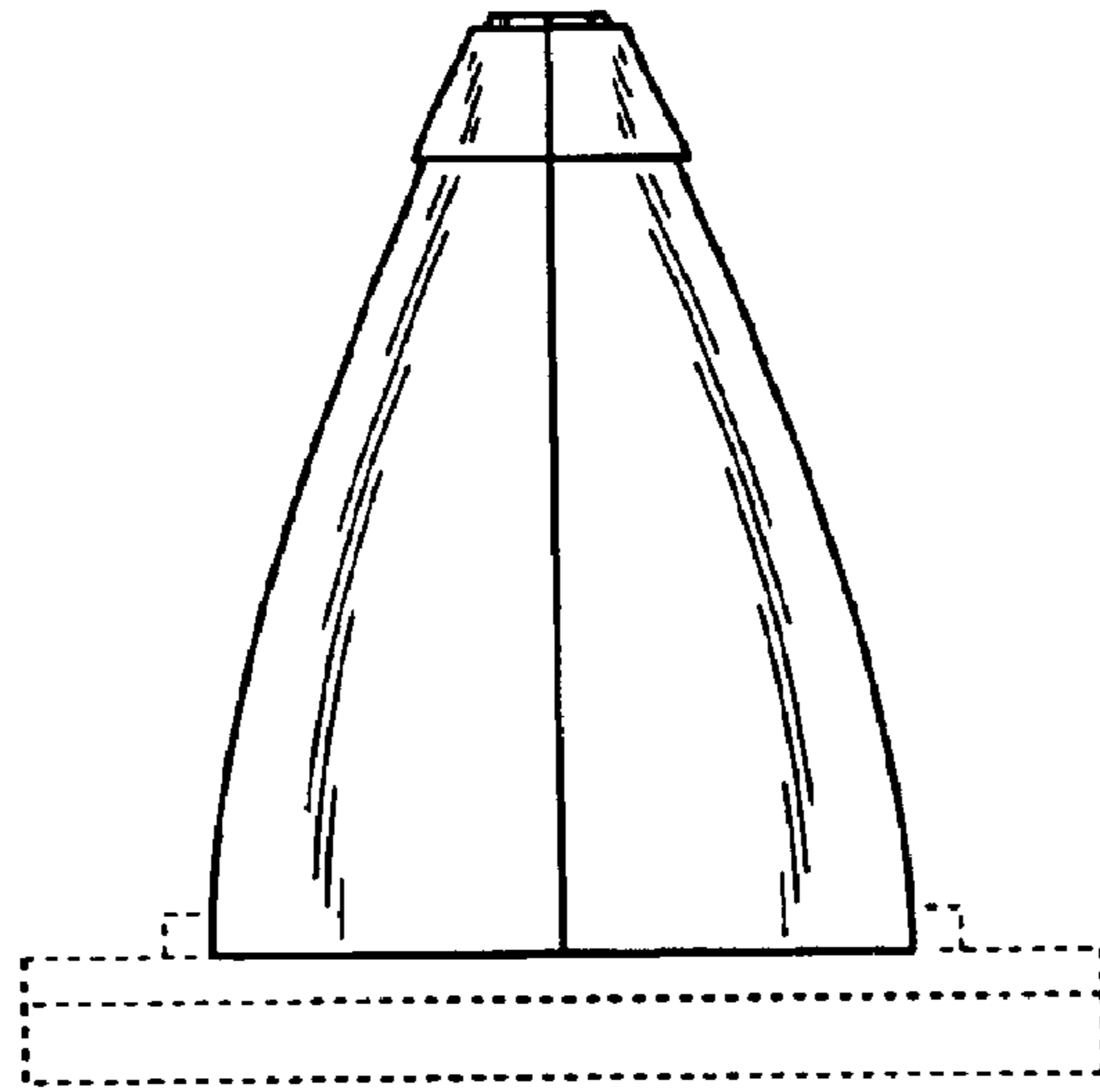


FIG. 16

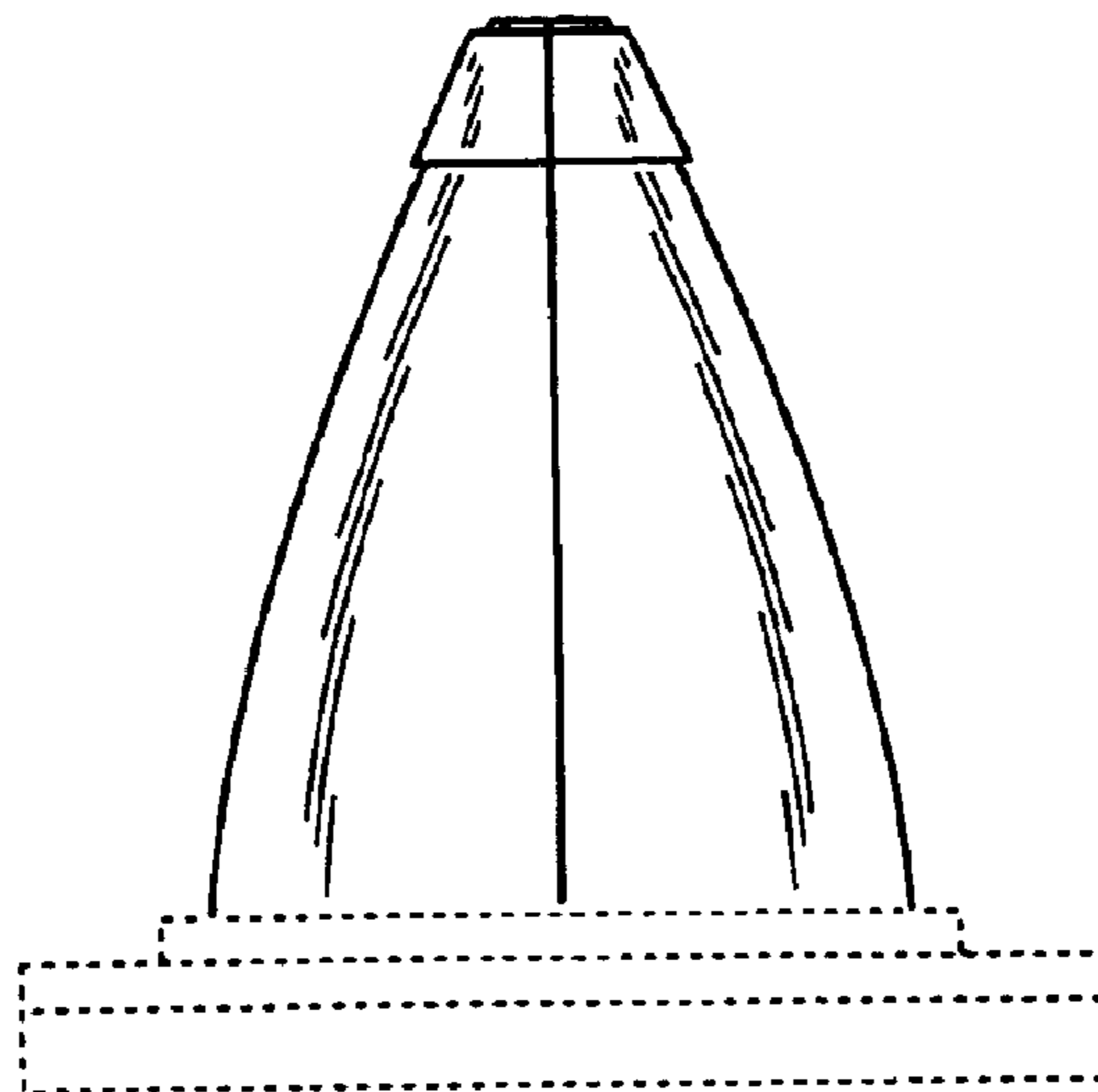


FIG. 17

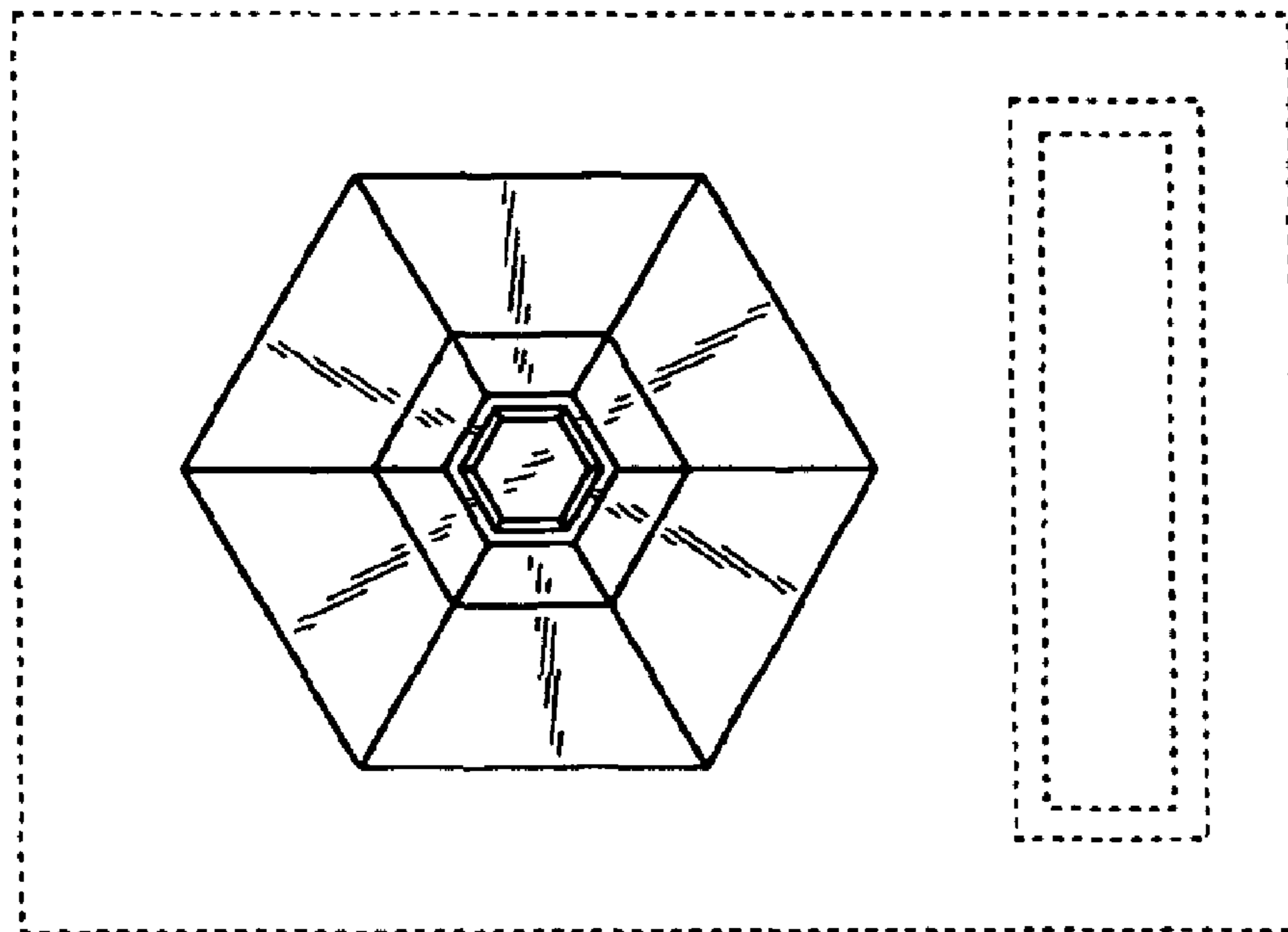


FIG. 18

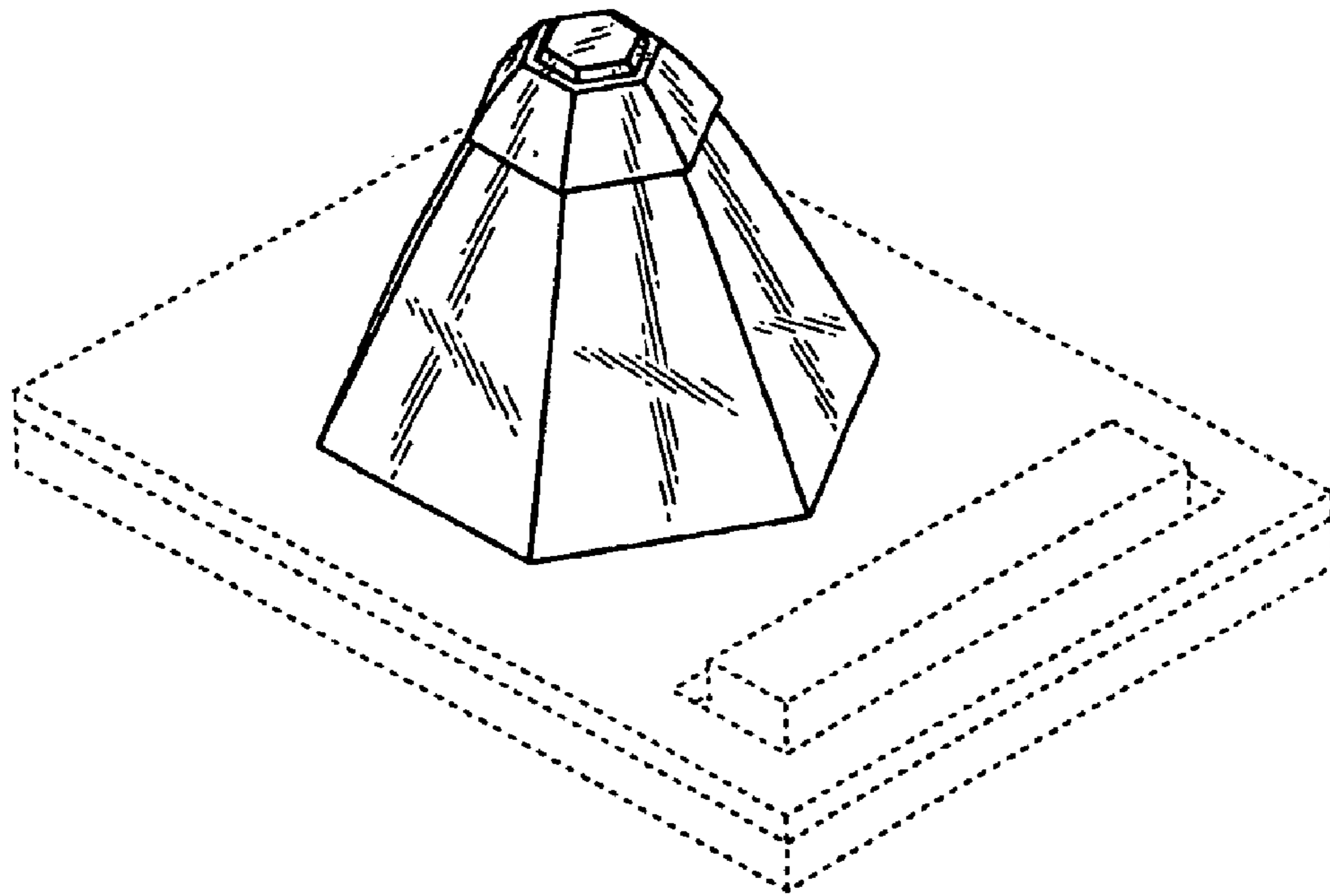


FIG. 19

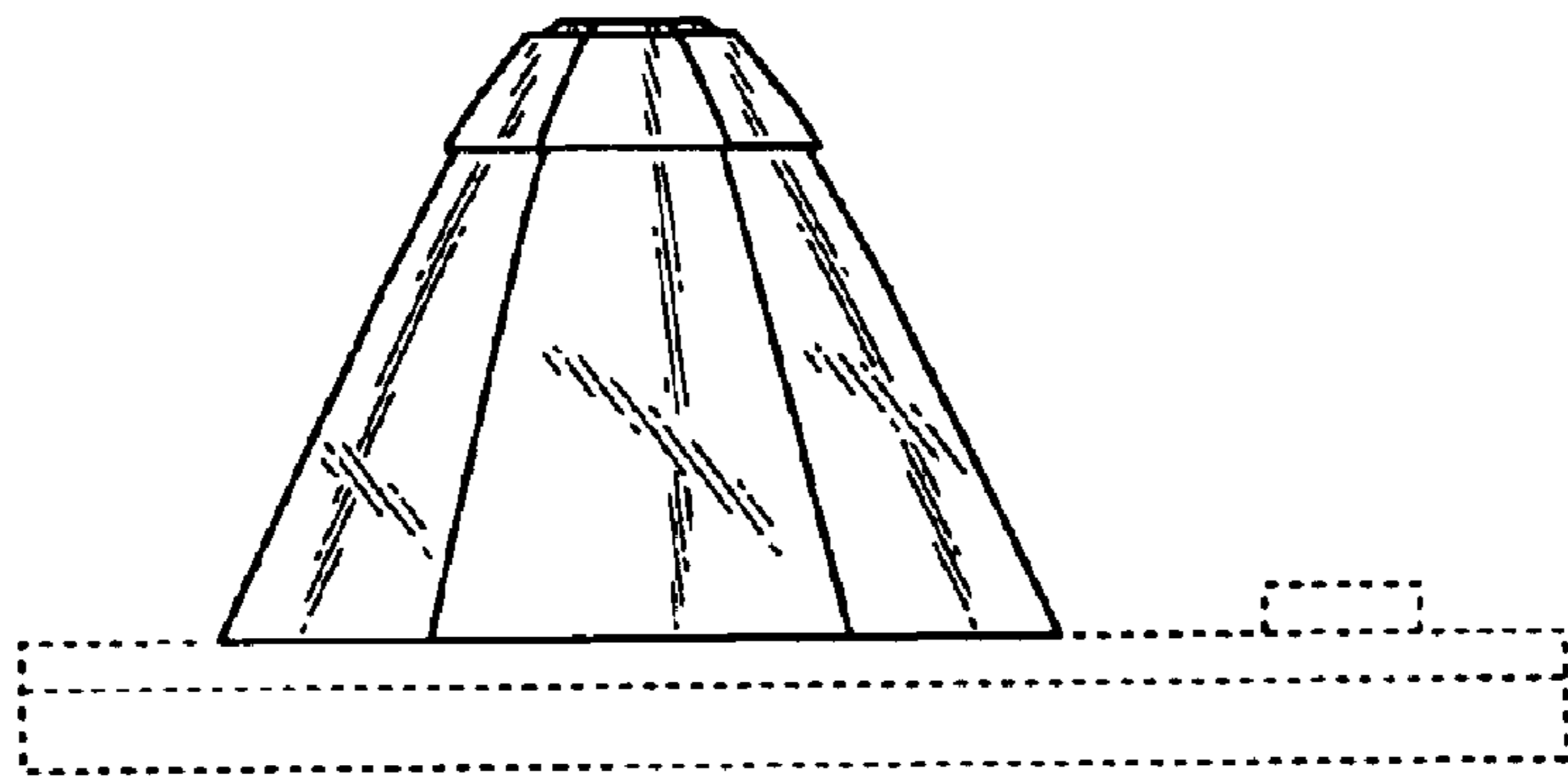


FIG. 20

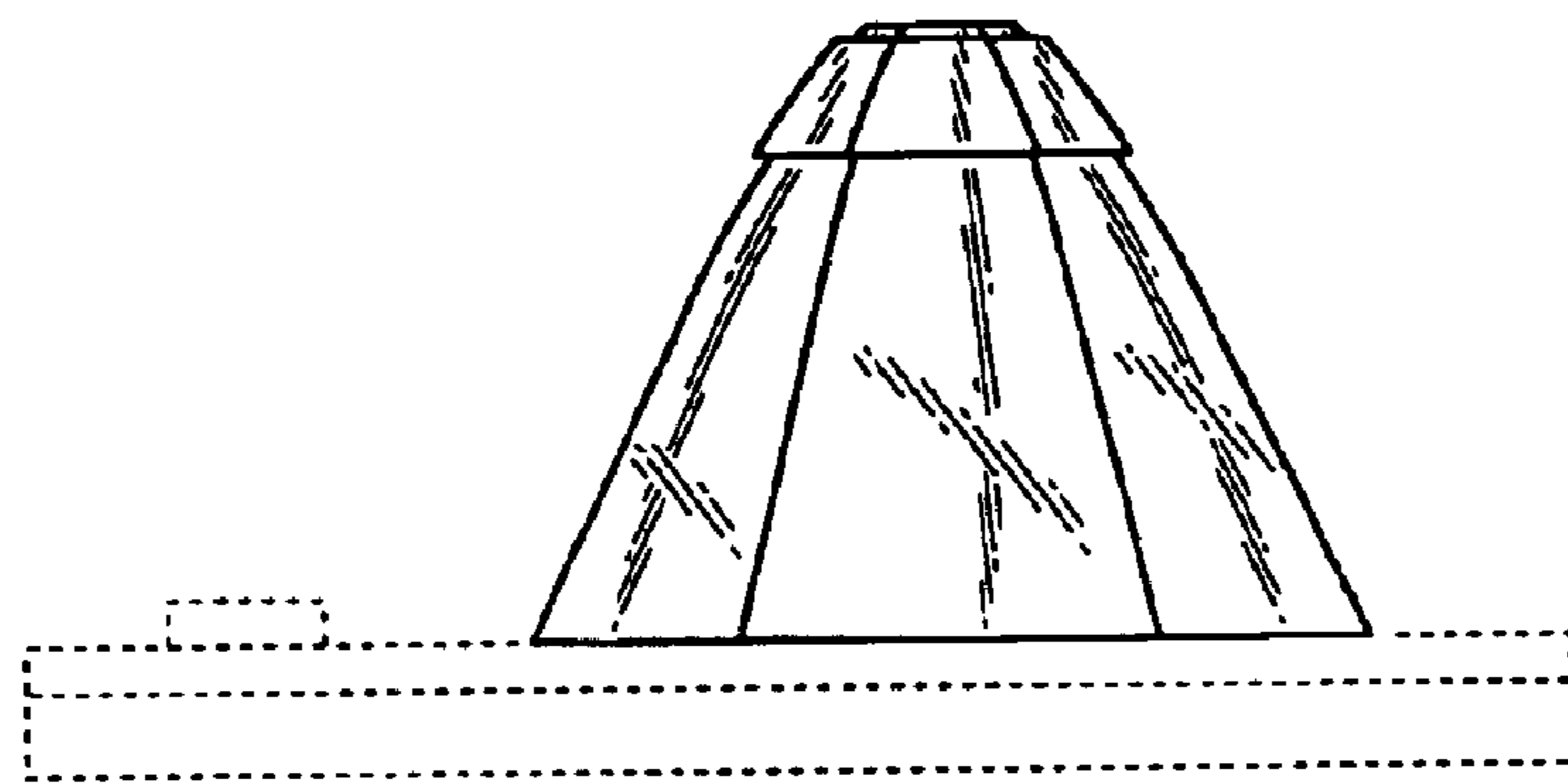


FIG. 21



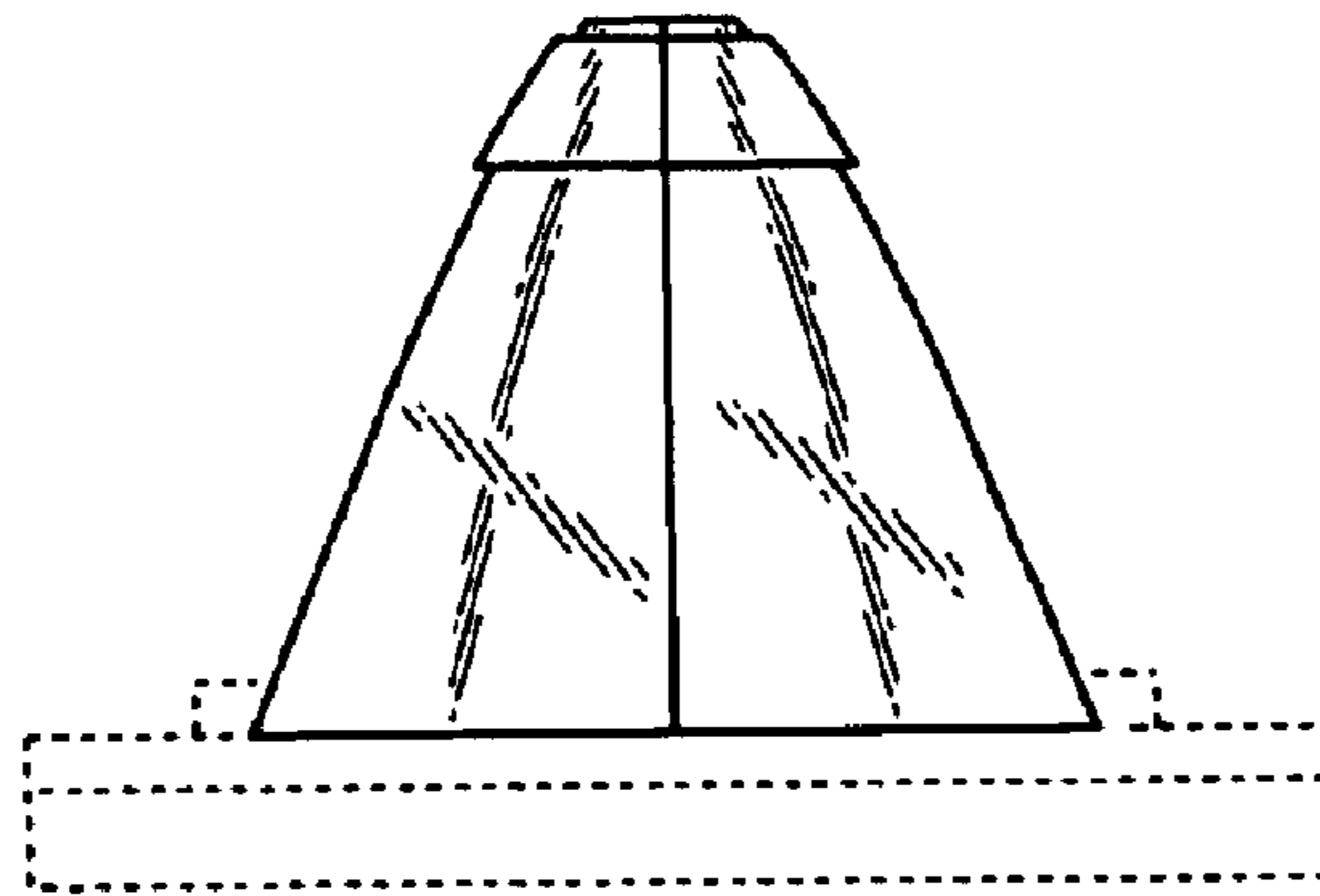


FIG. 22

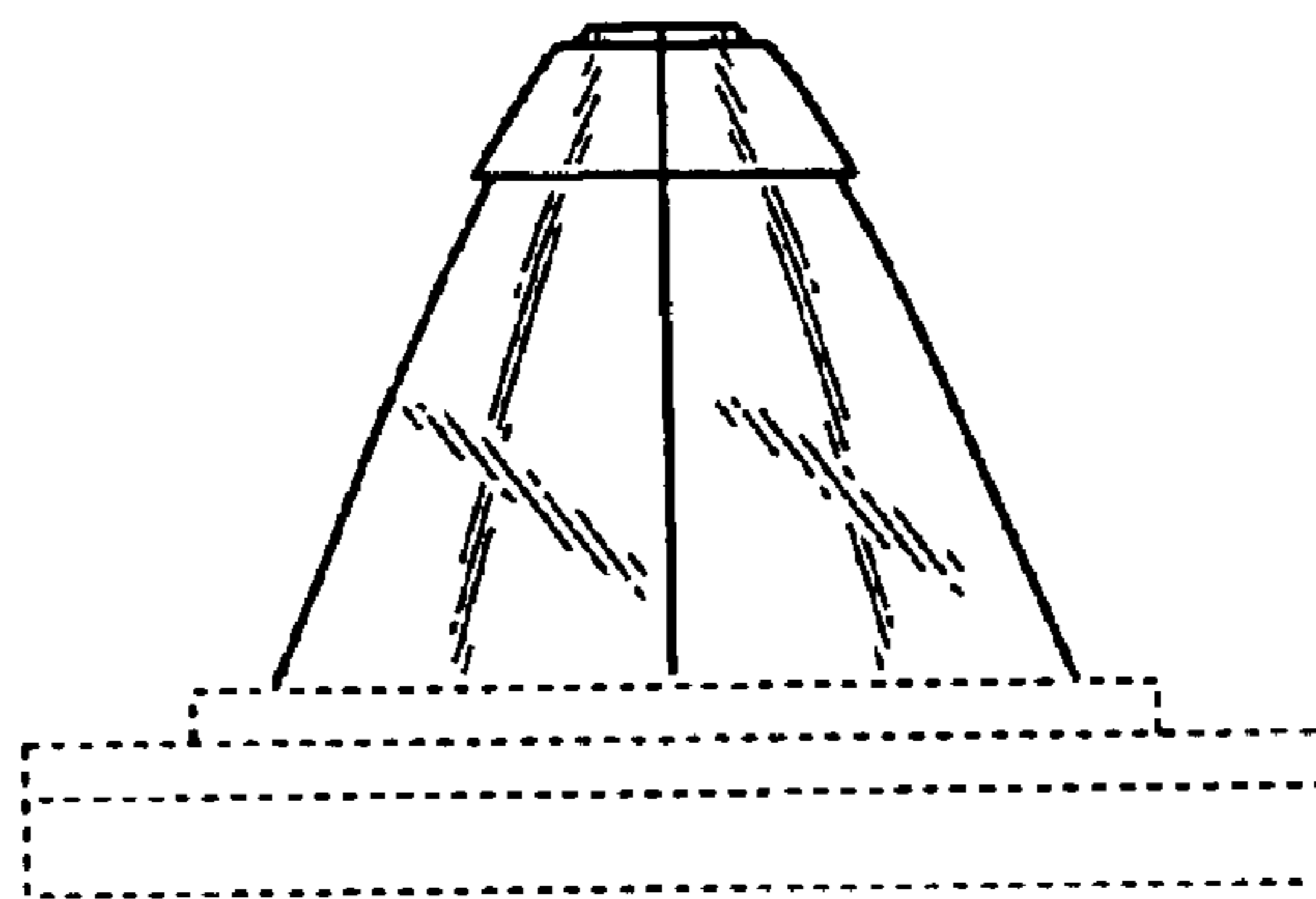


FIG. 23

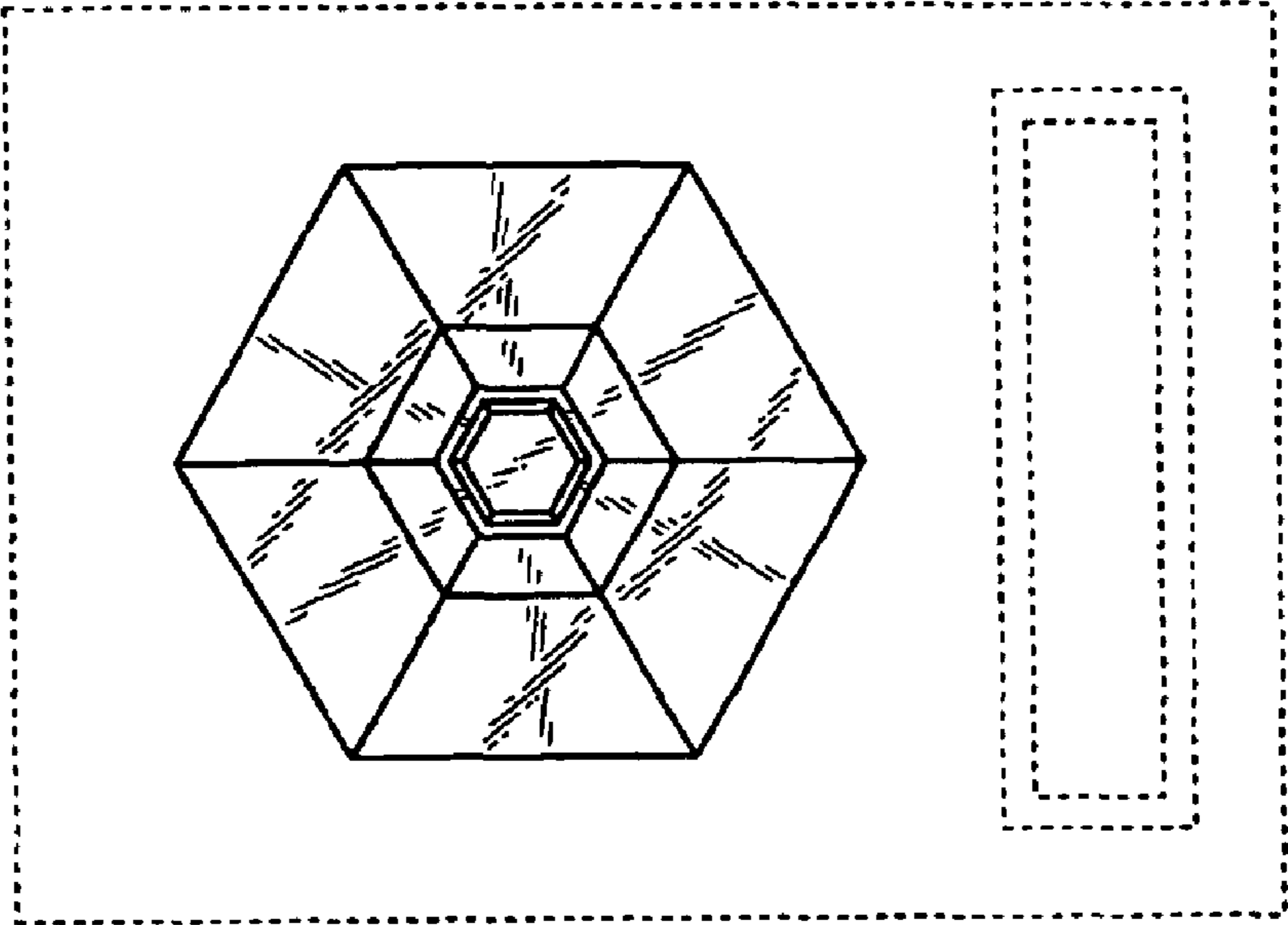


FIG. 24

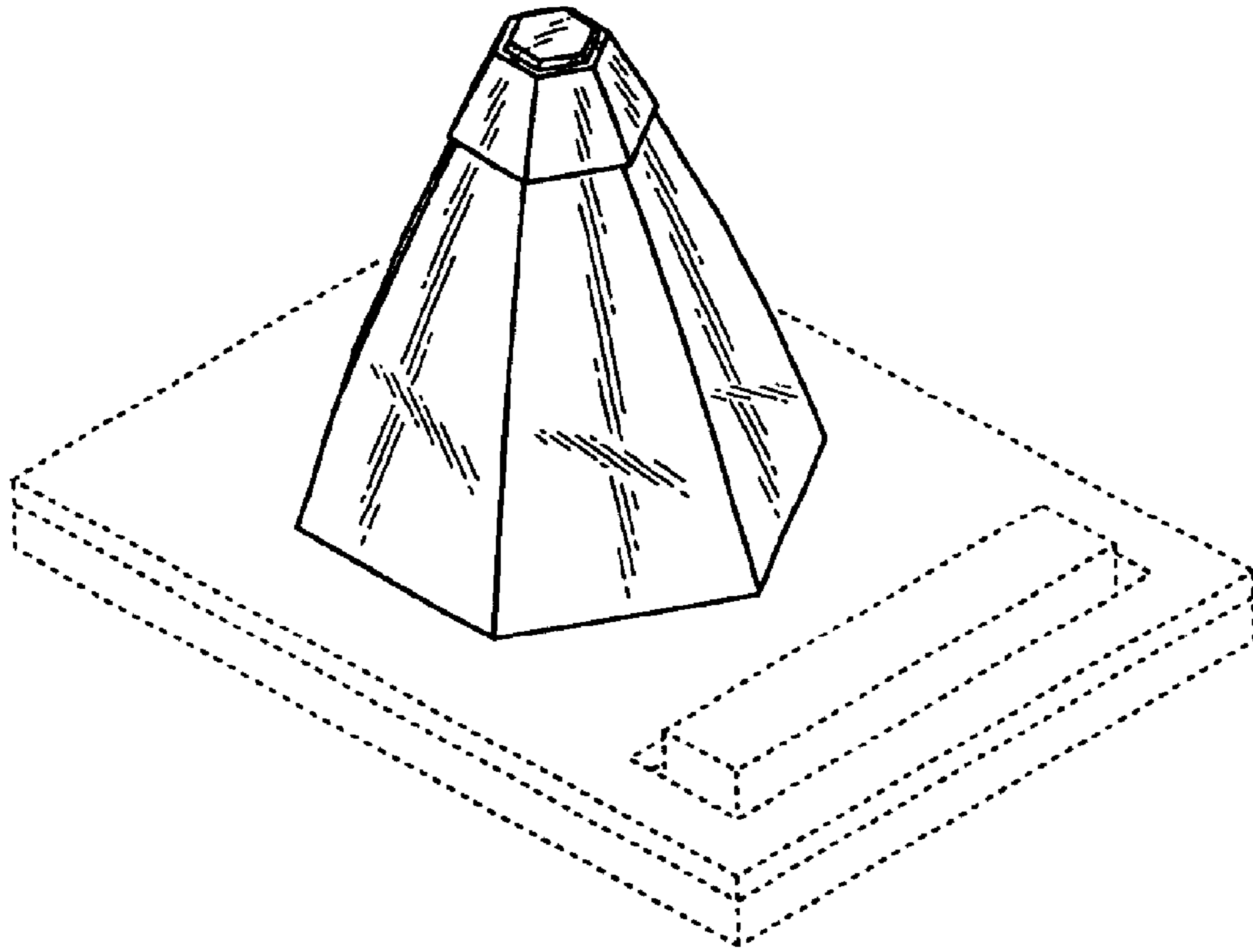


FIG. 25

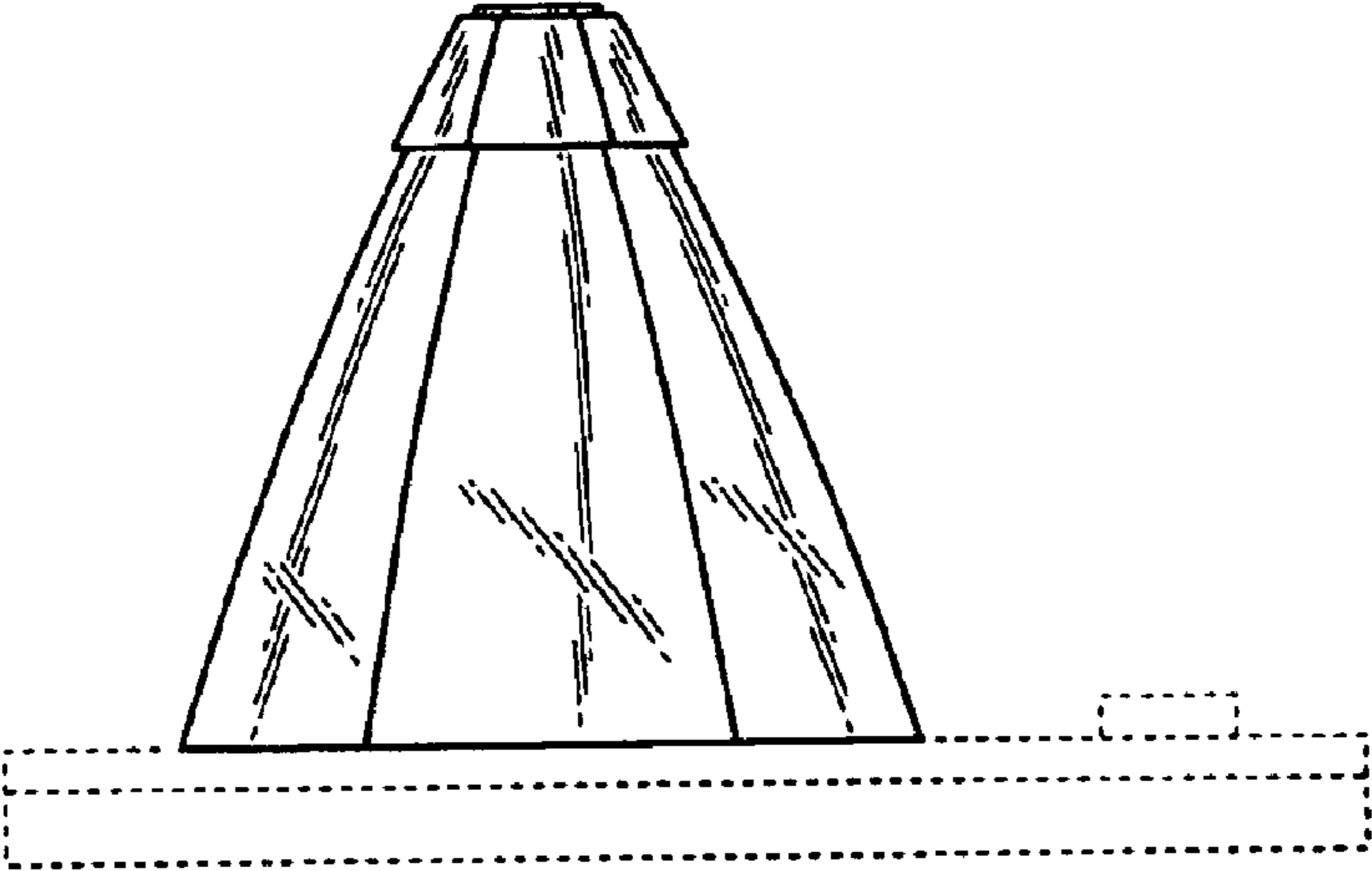


FIG. 26

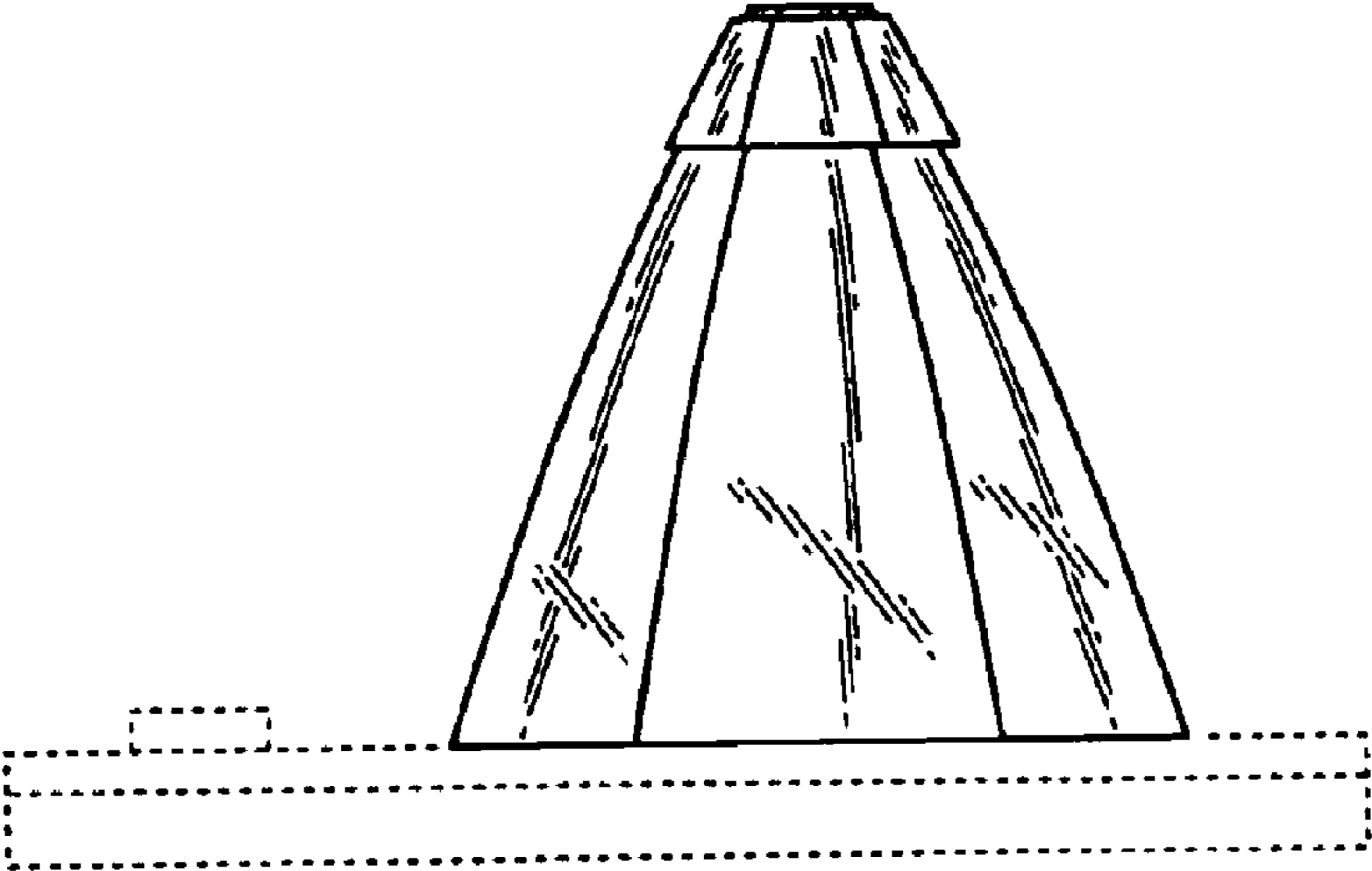


FIG. 27

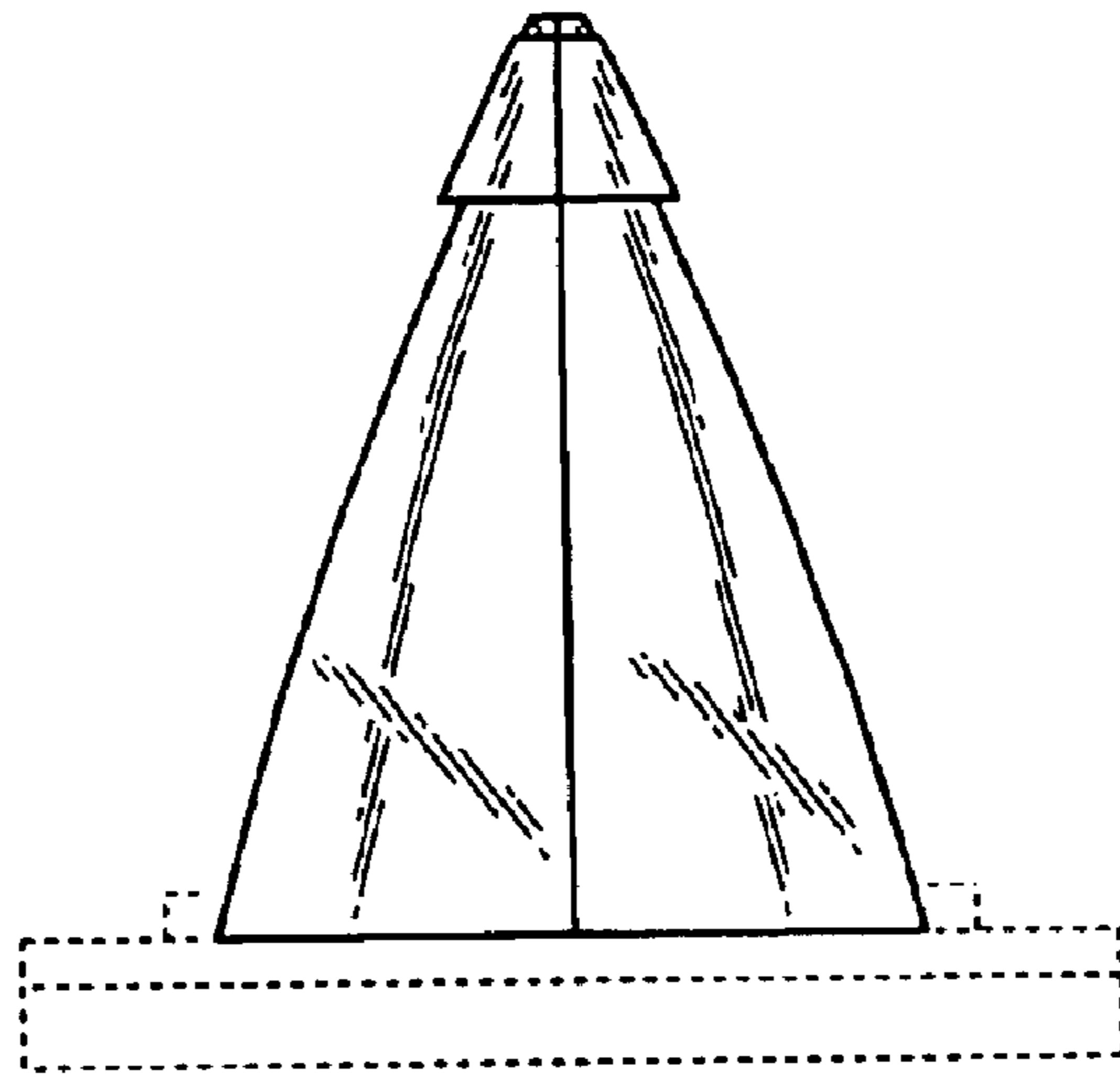


FIG. 28

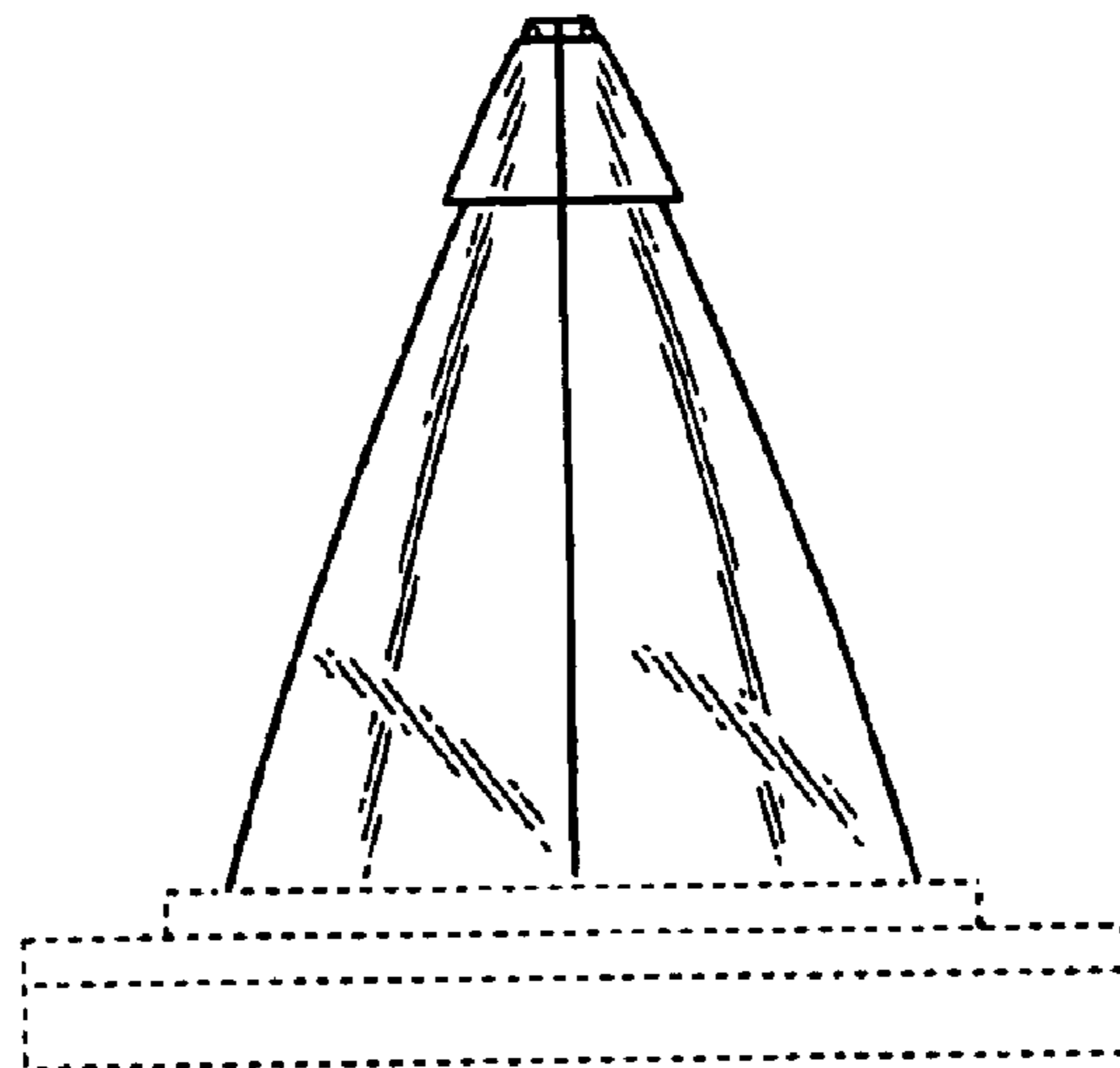
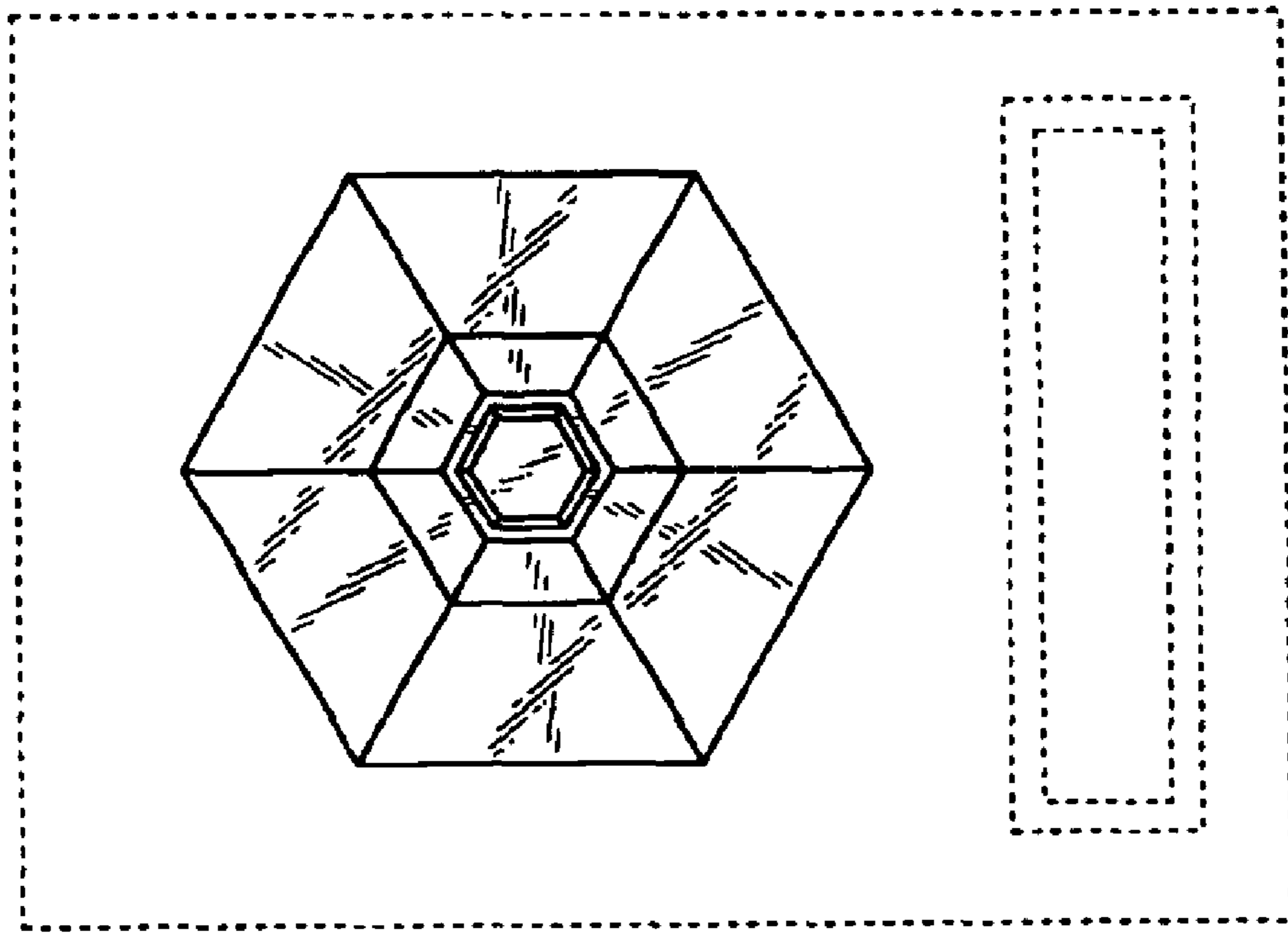
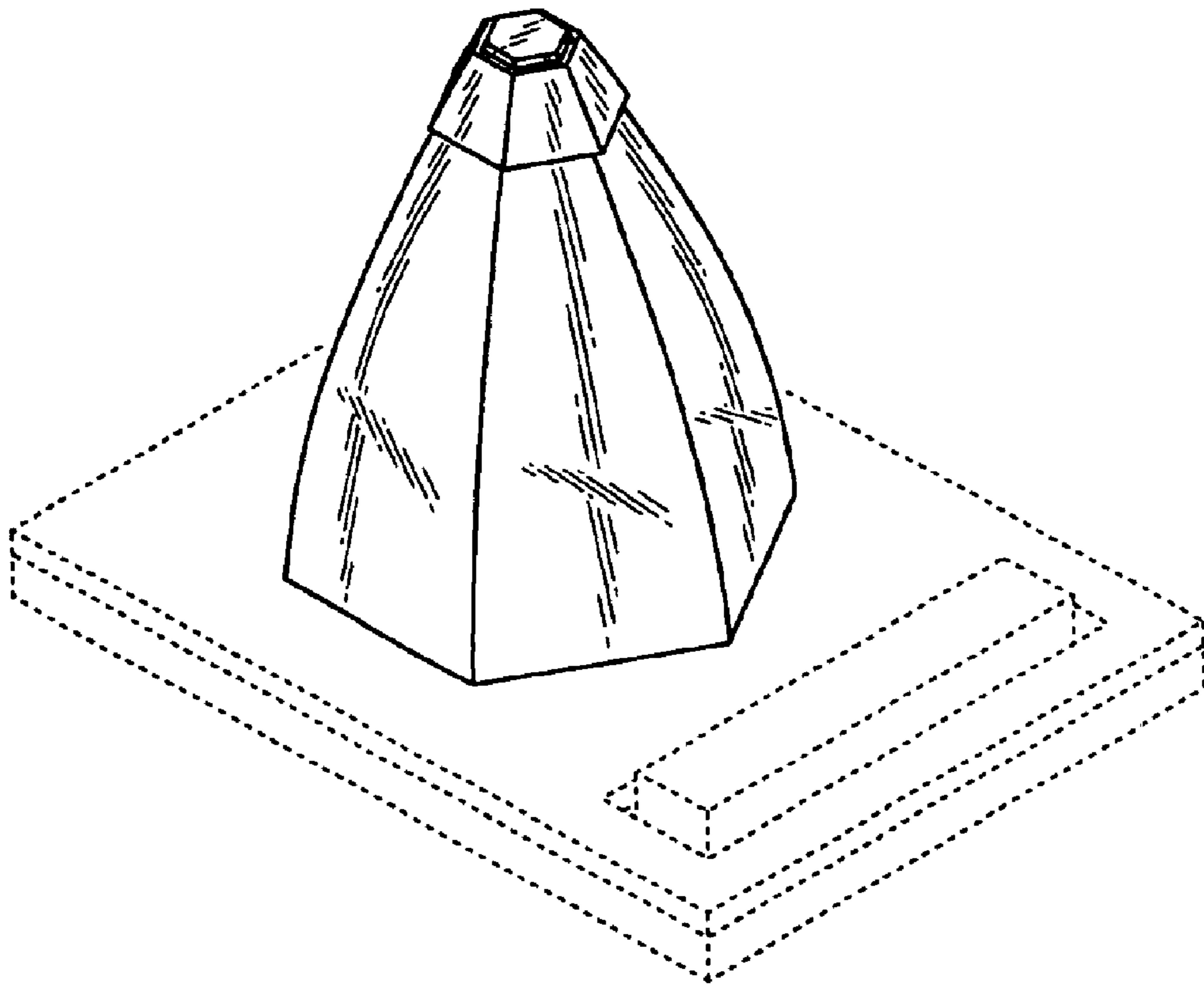


FIG. 29



**FIG. 30**



**FIG. 31**

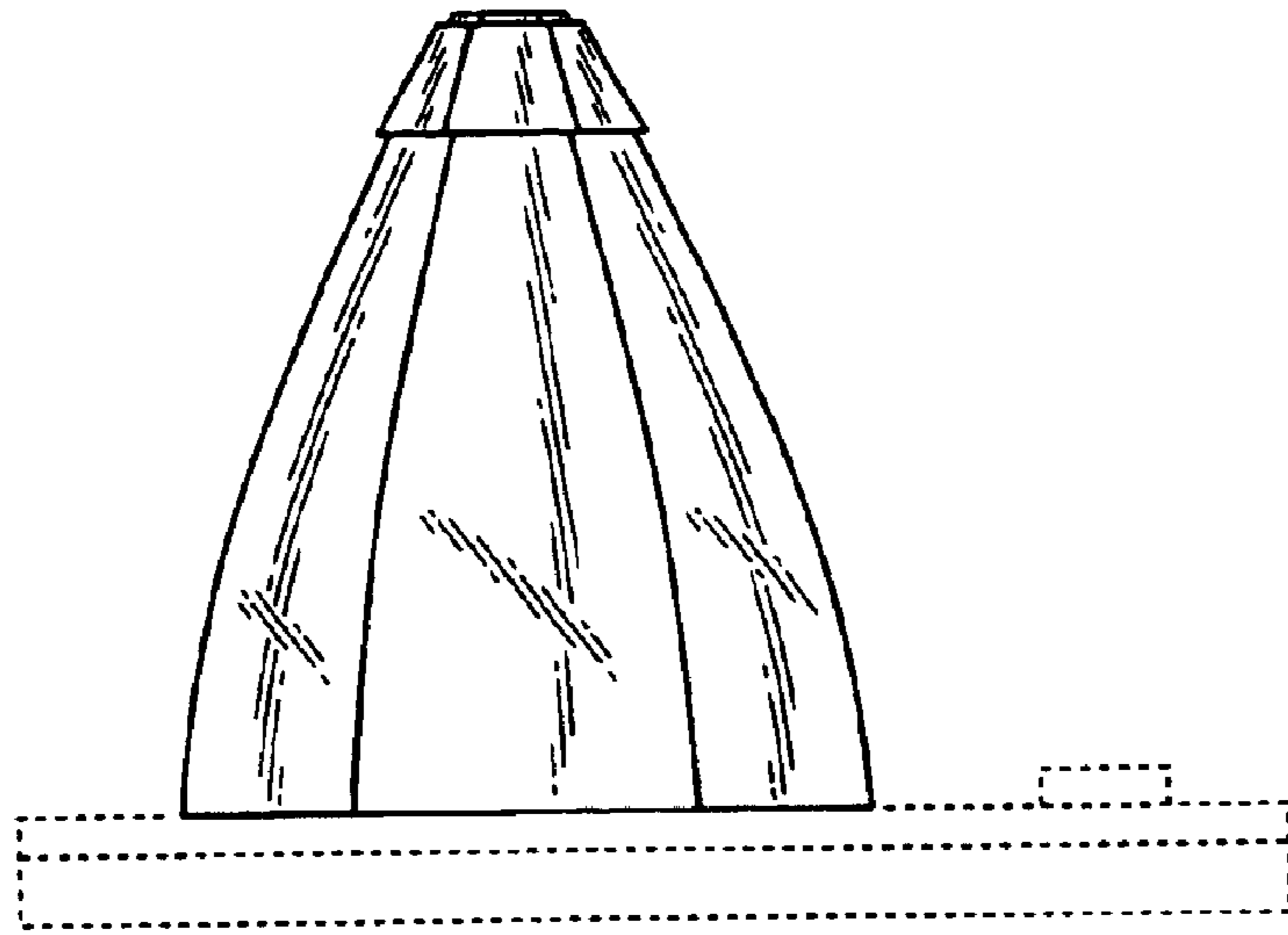


FIG. 32

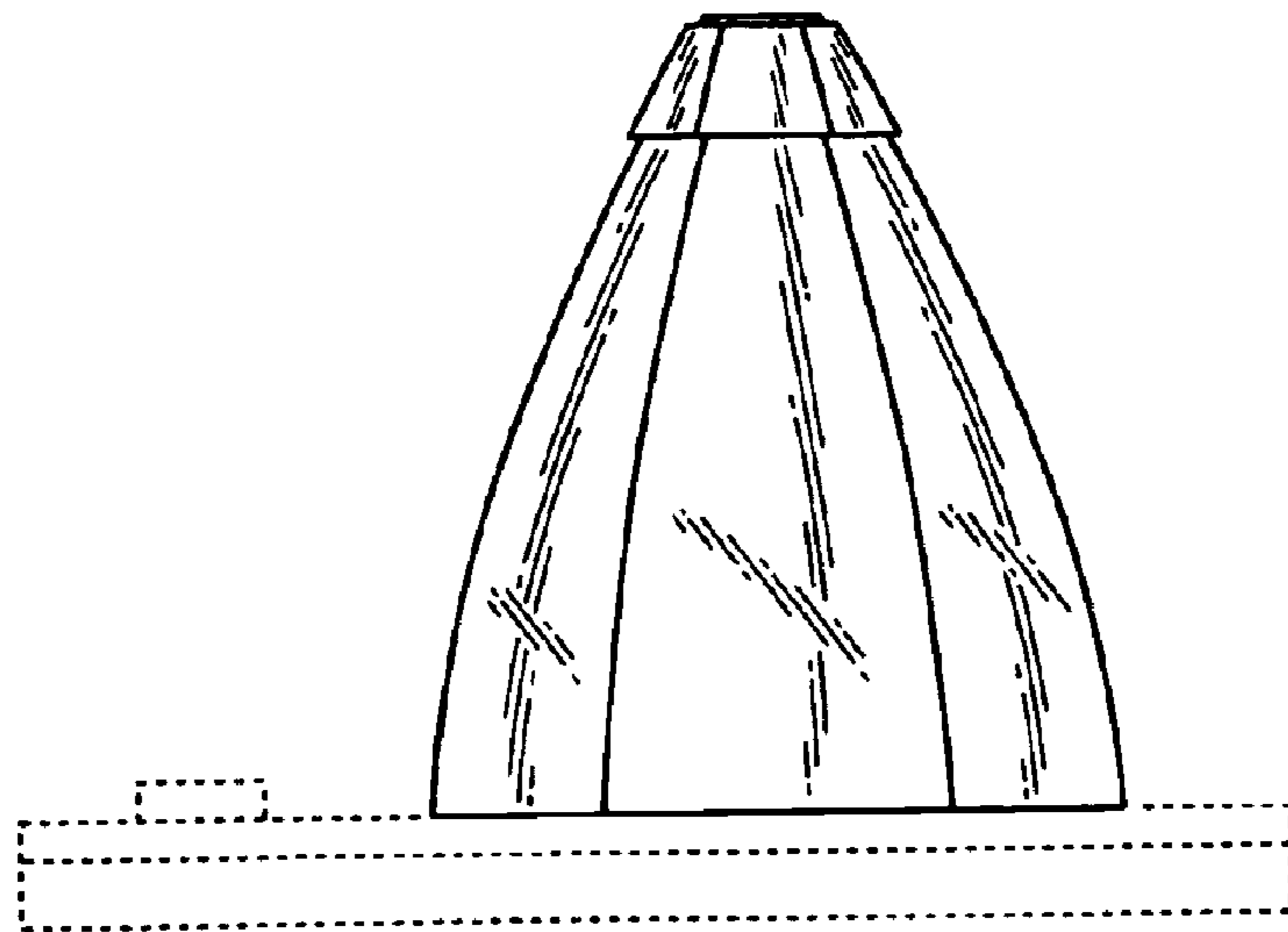


FIG. 33



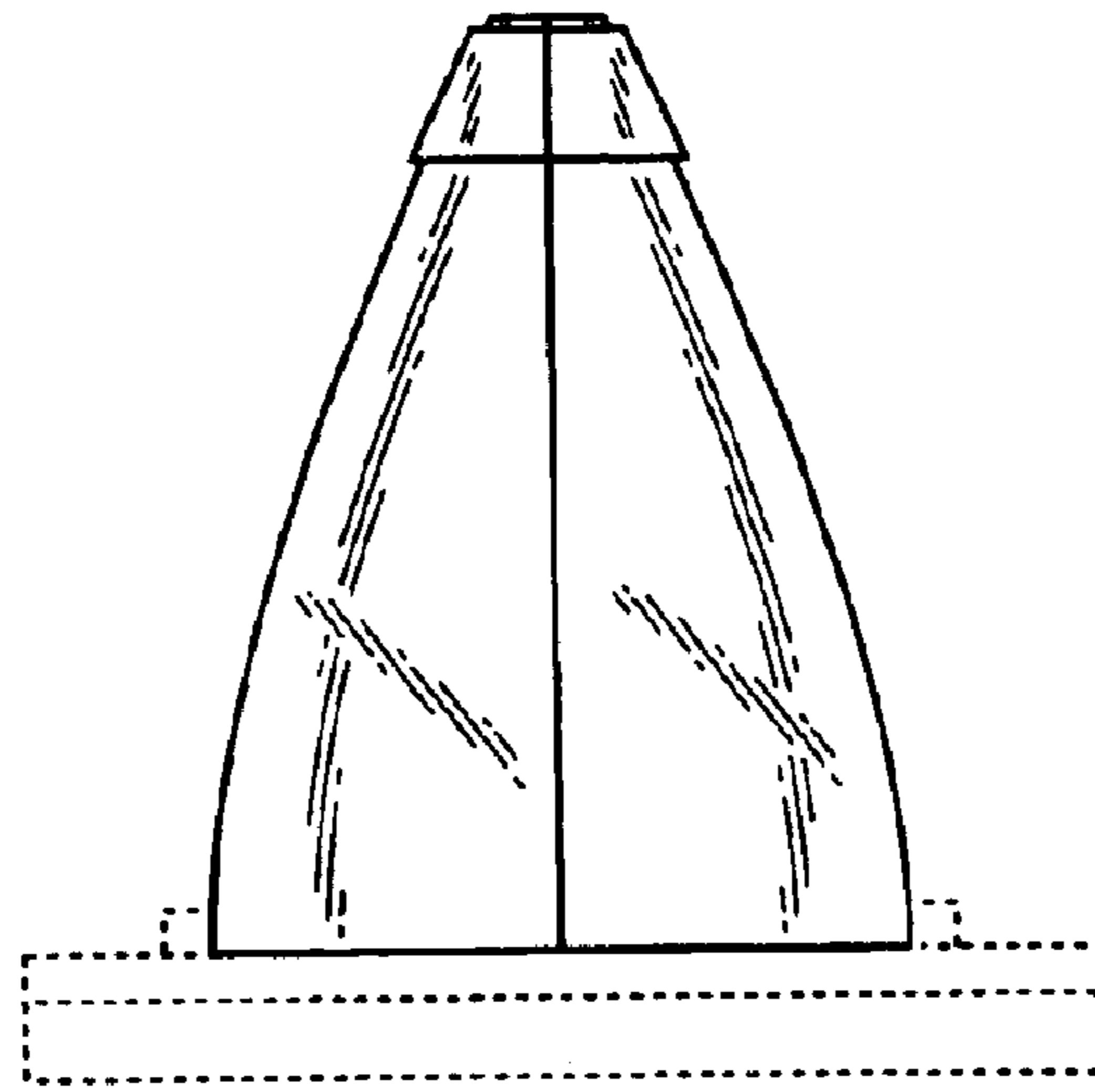


FIG. 34

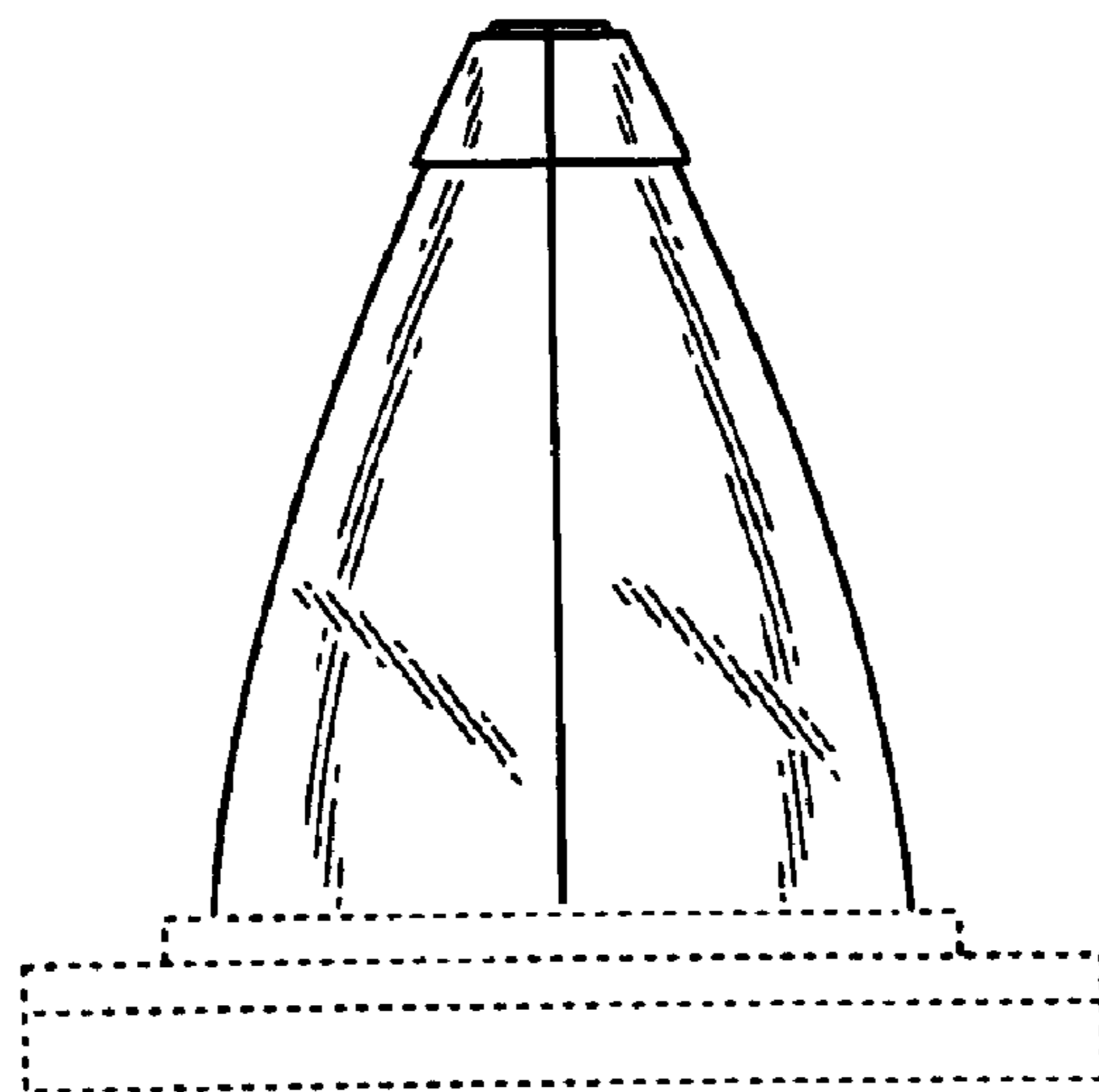


FIG. 35

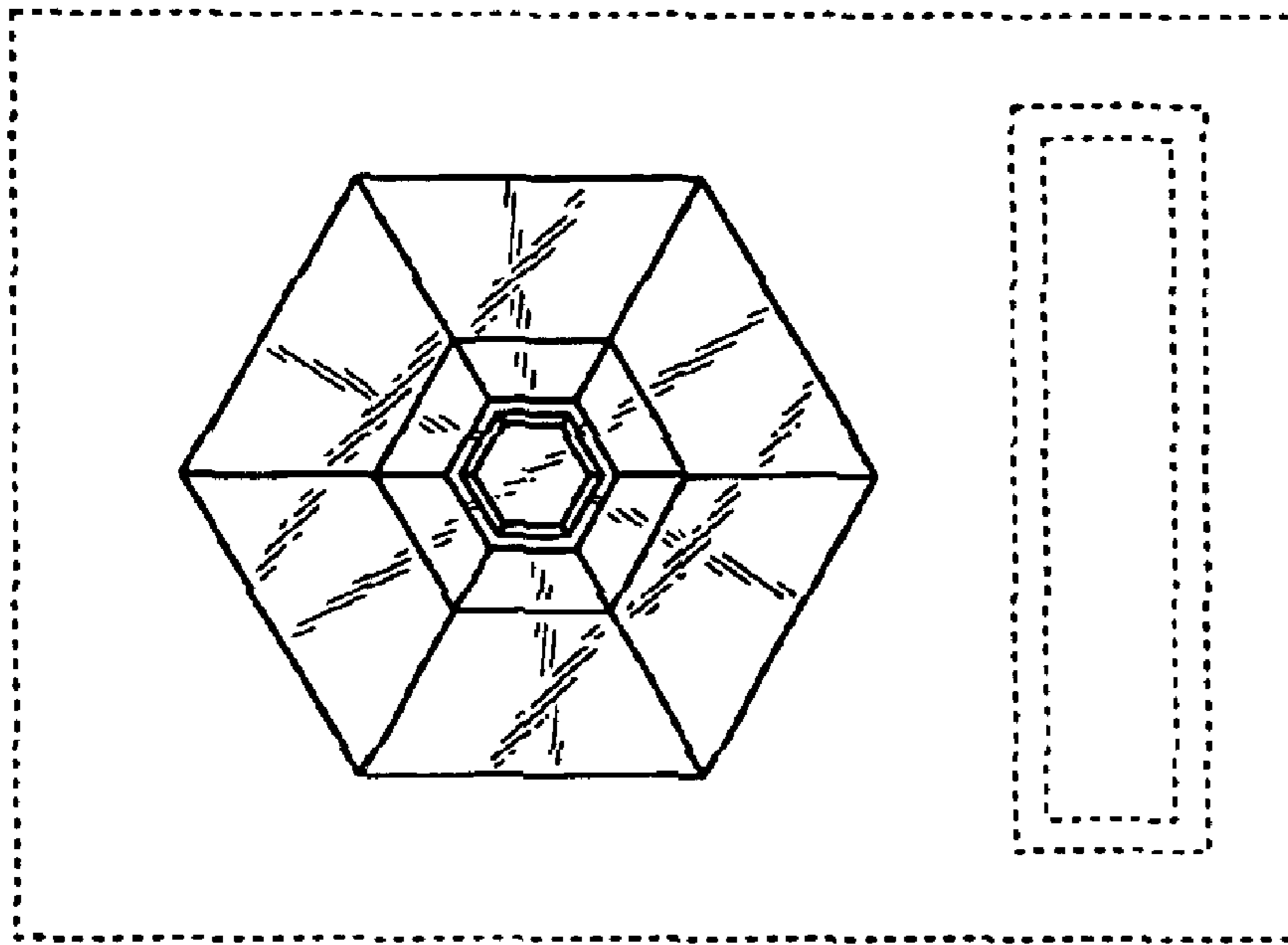


FIG. 36